

100-pin TQFP & 165-bump BGA  
Industrial Temp

512K x 18, 256K x 32, 256K x 36  
9Mb Sync Burst SRAMs

250 MHz–150 MHz  
1.8 V or 2.5 V  $V_{DD}$   
1.8 V or 2.5 V I/O

## Features

- IEEE 1149.1 JTAG-compatible Boundary Scan
- 1.8 V or 2.5 V +10%/–10% core power supply
- 1.8 V or 2.5 V I/O supply
- $\overline{LBO}$  pin for Linear or Interleaved Burst mode
- Internal input resistors on mode pins allow floating mode pins
- Byte Write ( $\overline{BW}$ ) and/or Global Write ( $\overline{GW}$ ) operation
- Internal self-timed write cycle
- Automatic power-down for portable applications
- JEDEC-standard 100-lead TQFP and 165-bump BGA packages
- RoHS-compliant 100-lead TQFP and 165-bump BGA packages available

## Functional Description

### Applications

The GS88118/32/36C(T/D)-xxxIV is a 9,437,184-bit high performance synchronous SRAM with a 2-bit burst address counter. Although of a type originally developed for Level 2 Cache applications supporting high performance CPUs, the device now finds application in synchronous SRAM applications, ranging from DSP main store to networking chip set support.

### Controls

Addresses, data I/Os, chip enable ( $\overline{E1}$ ,  $E2$ ), address burst control inputs ( $\overline{ADSP}$ ,  $\overline{ADSC}$ ,  $\overline{ADV}$ ) and write control inputs ( $\overline{Bx}$ ,  $\overline{BW}$ ,  $\overline{GW}$ ) are synchronous and are controlled by a positive-edge-triggered clock input (CK). Output enable ( $\overline{G}$ ) and power down control (ZZ) are asynchronous inputs. Burst cycles can be initiated with either  $\overline{ADSP}$  or  $\overline{ADSC}$  inputs. In Burst mode, subsequent burst addresses are generated internally and are controlled by  $\overline{ADV}$ . The burst address counter may be configured to count in either linear or

interleave order with the Linear Burst Order ( $\overline{LBO}$ ) input. The Burst function need not be used. New addresses can be loaded on every cycle with no degradation of chip performance.

### Flow Through/Pipeline Reads

The function of the Data Output register can be controlled by the user via the  $\overline{FT}$  mode pin (Pin 14). Holding the  $\overline{FT}$  mode pin low places the RAM in Flow Through mode, causing output data to bypass the Data Output Register. Holding  $\overline{FT}$  high places the RAM in Pipeline mode, activating the rising-edge-triggered Data Output Register.

### SCD Pipelined Reads

The GS88118/32/36C(T/D)-xxxIV is a SCD (Single Cycle Deselect) pipelined synchronous SRAM. DCD (Dual Cycle Deselect) versions are also available. SCD SRAMs pipeline deselect commands one stage less than read commands. SCD RAMs begin turning off their outputs immediately after the deselect command has been captured in the input registers.

### Byte Write and Global Write

Byte write operation is performed by using Byte Write enable ( $\overline{BW}$ ) input combined with one or more individual byte write signals ( $\overline{Bx}$ ). In addition, Global Write ( $\overline{GW}$ ) is available for writing all bytes at one time, regardless of the Byte Write control inputs.

### Sleep Mode

Low power (Sleep mode) is attained through the assertion (High) of the ZZ signal, or by stopping the clock (CK). Memory data is retained during Sleep mode.

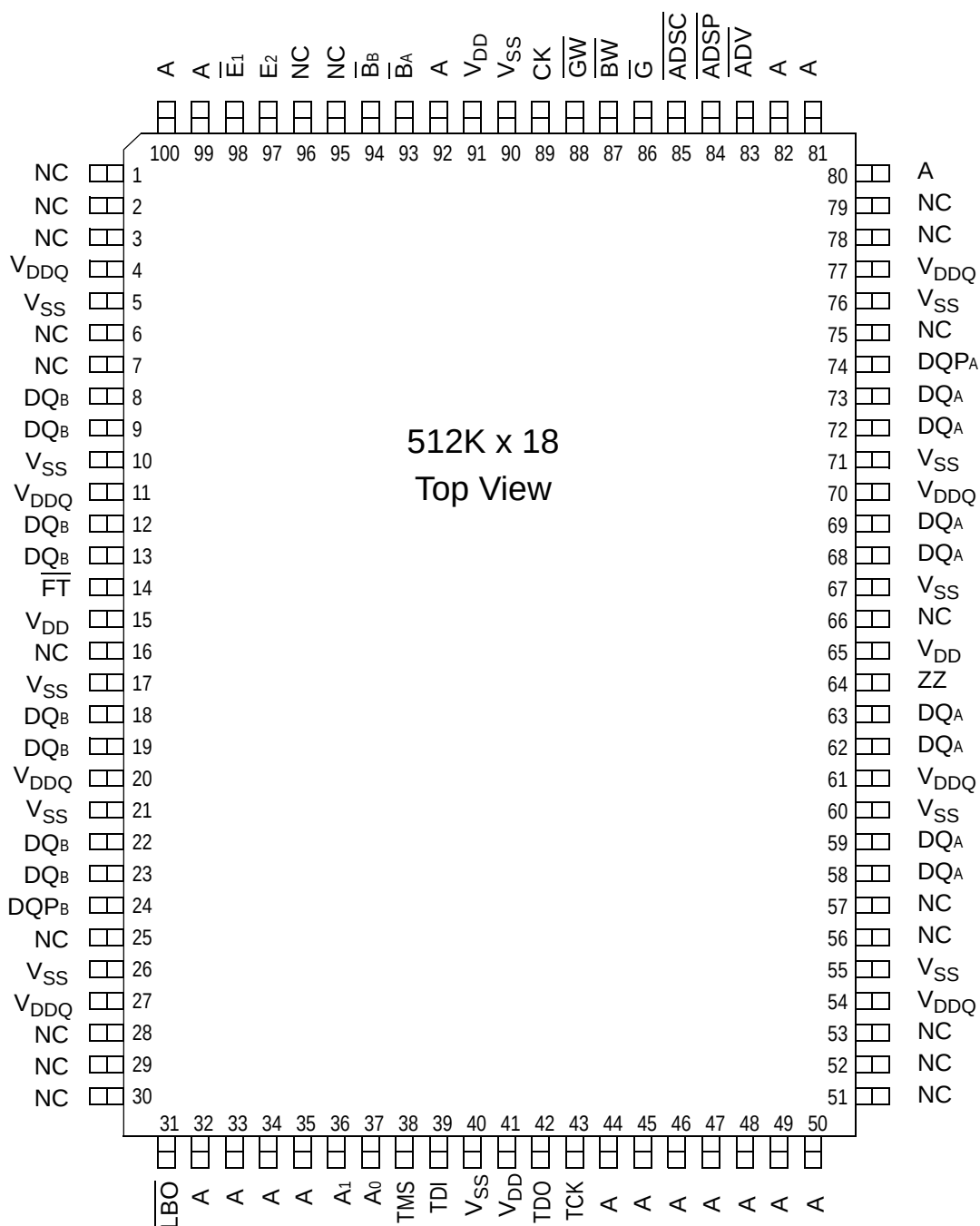
### Core and Interface Voltages

The GS88118/32/36C(T/D)-xxxIV operates on a 1.8 V or 2.5 V power supply. All input are 1.8 V and 2.5 V compatible. Separate output power ( $V_{DDQ}$ ) pins are used to decouple output noise from the internal circuits and are 1.8 V and 2.5 V compatible.

## Parameter Synopsis

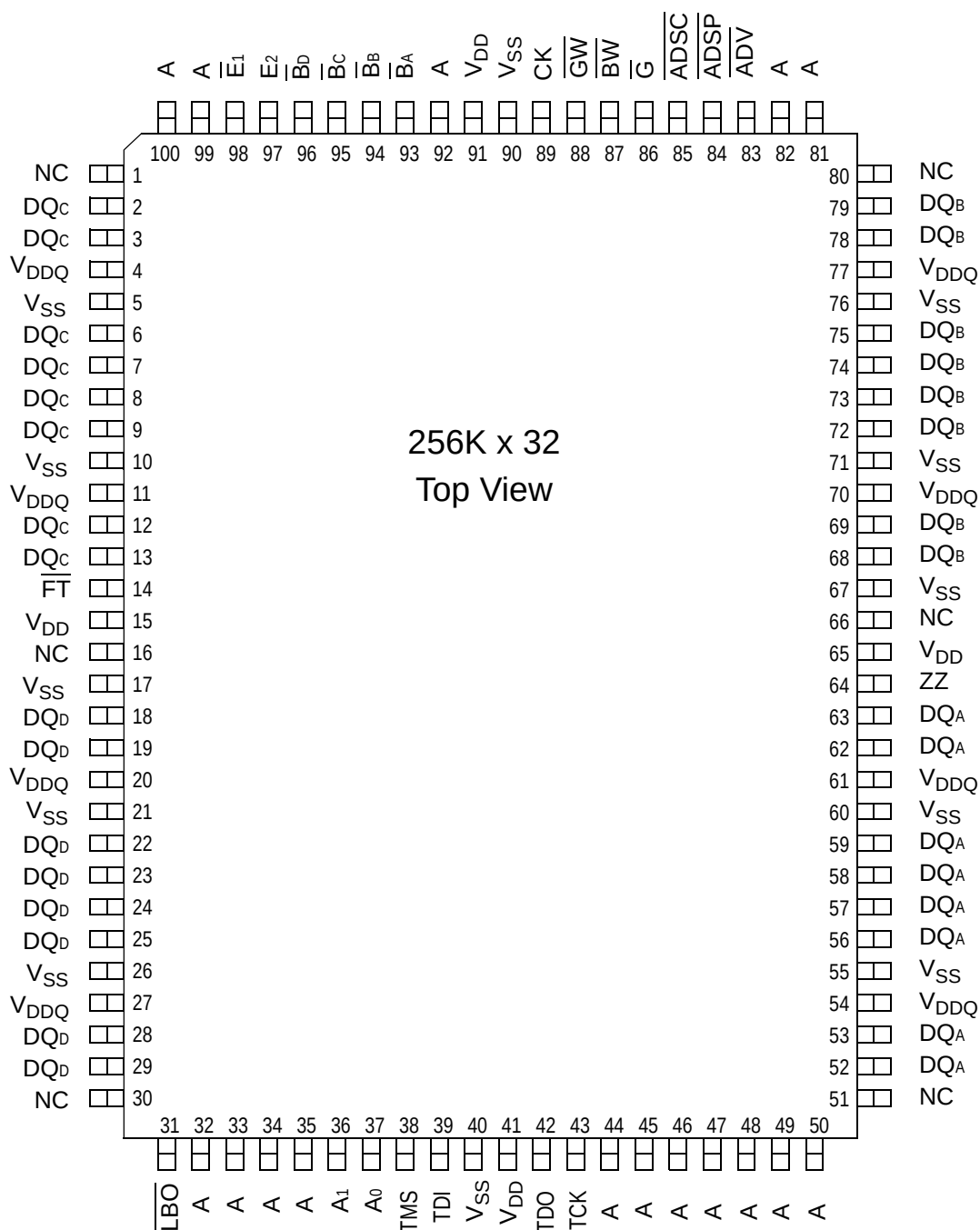
|                         |                | -250I | -200I | -150I | Unit |
|-------------------------|----------------|-------|-------|-------|------|
| Pipeline<br>3-1-1-1     | $t_{KQ}$       | 3.0   | 3.0   | 3.8   | ns   |
|                         | tCycle         | 4.0   | 5.0   | 6.7   | ns   |
|                         | Curr (x18)     | 195   | 170   | 145   | mA   |
|                         | Curr (x32/x36) | 220   | 185   | 165   | mA   |
| Flow Through<br>2-1-1-1 | $t_{KQ}$       | 5.5   | 6.5   | 7.5   | ns   |
|                         | tCycle         | 5.5   | 6.5   | 7.5   | ns   |
|                         | Curr (x18)     | 155   | 135   | 133   | mA   |
|                         | Curr (x32/x36) | 175   | 160   | 145   | mA   |

## GS88118CT-xxxIV 100-Pin TQFP Pinout (Package T)


**Note:**

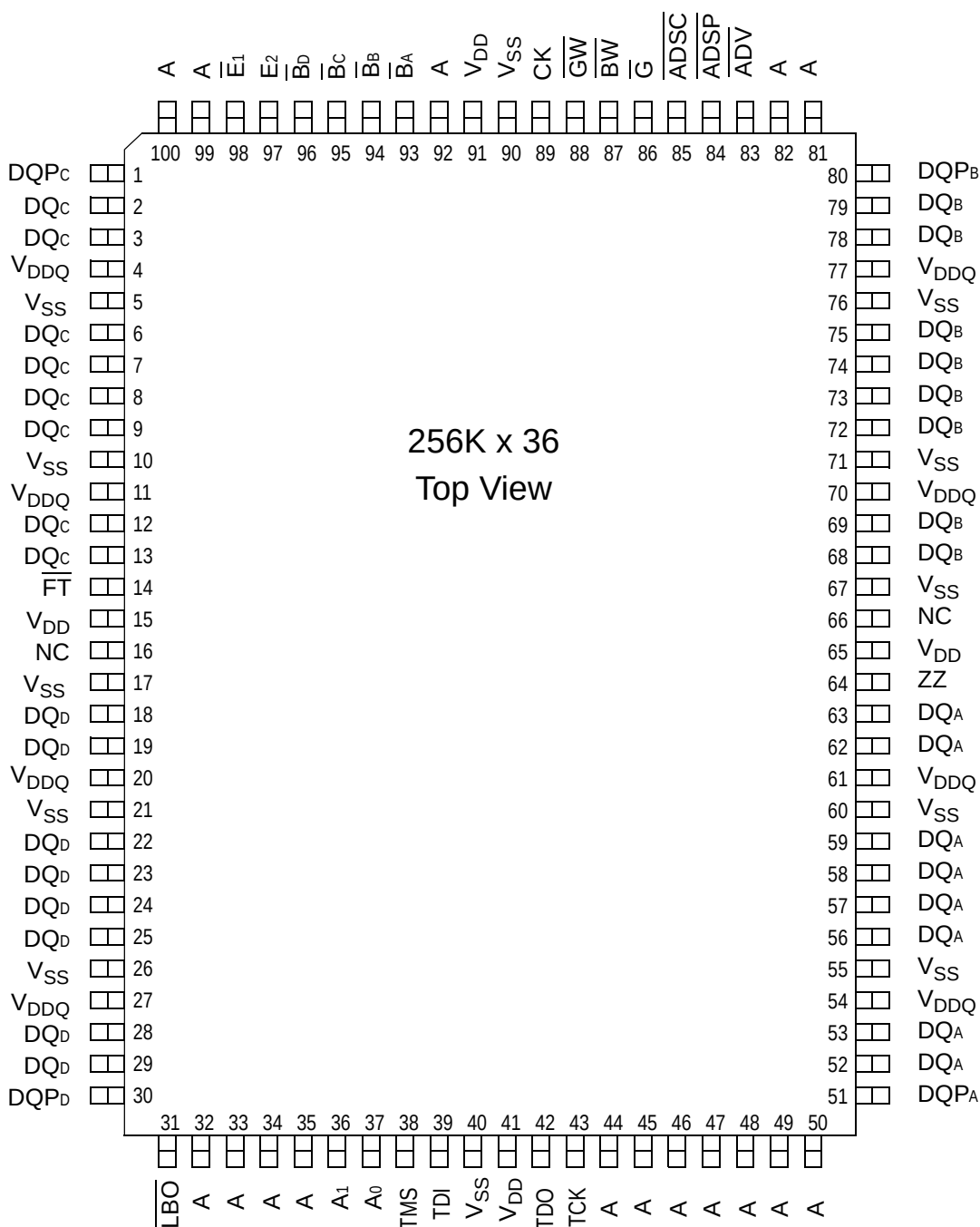
Pins marked with NC can be tied to either  $V_{DD}$  or  $V_{SS}$ . These pins can also be left floating.

## GS88132CT-xxxIV 100-Pin TQFP Pinout (Package T)


**Note:**

Pins marked with NC can be tied to either VDD or VSS. These pins can also be left floating.

## GS88136CT-xxxIV 100-Pin TQFP Pinout (Package T)


**Note:**

Pins marked with NC can be tied to either VDD or VSS. These pins can also be left floating.

## TQFP Pin Description

| Symbol                                                                                                                           | Type | Description                                                                   |
|----------------------------------------------------------------------------------------------------------------------------------|------|-------------------------------------------------------------------------------|
| A <sub>0</sub> , A <sub>1</sub>                                                                                                  | I    | Address field LSBs and Address Counter preset Inputs                          |
| A                                                                                                                                | I    | Address Inputs                                                                |
| DQ <sub>A</sub><br>DQ <sub>B</sub><br>DQ <sub>C</sub><br>DQ <sub>D</sub>                                                         | I/O  | Data Input and Output pins                                                    |
| NC                                                                                                                               | —    | No Connect                                                                    |
| $\overline{\text{BW}}$                                                                                                           | I    | Byte Write—Writes all enabled bytes; active low                               |
| $\overline{\text{B}}_{\text{A}}, \overline{\text{B}}_{\text{B}}, \overline{\text{B}}_{\text{C}}, \overline{\text{B}}_{\text{D}}$ | I    | Byte Write Enable for DQ <sub>A</sub> , DQ <sub>B</sub> Data I/Os; active low |
| CK                                                                                                                               | I    | Clock Input Signal; active high                                               |
| $\overline{\text{GW}}$                                                                                                           | I    | Global Write Enable—Writes all bytes; active low                              |
| $\overline{\text{E}}_1$                                                                                                          | I    | Chip Enable; active low                                                       |
| E <sub>2</sub>                                                                                                                   | I    | Chip Enable; active high                                                      |
| $\overline{\text{G}}$                                                                                                            | I    | Output Enable; active low                                                     |
| $\overline{\text{ADV}}$                                                                                                          | I    | Burst address counter advance enable; active low                              |
| $\overline{\text{ADSP}}, \overline{\text{ADSC}}$                                                                                 | I    | Address Strobe (Processor, Cache Controller); active low                      |
| ZZ                                                                                                                               | I    | Sleep Mode control; active high                                               |
| TMS                                                                                                                              | I    | Scan Test Mode Select                                                         |
| TDI                                                                                                                              | I    | Scan Test Data In                                                             |
| TDO                                                                                                                              | O    | Scan Test Data Out                                                            |
| TCK                                                                                                                              | I    | Scan Test Clock                                                               |
| $\overline{\text{FT}}$                                                                                                           | I    | Flow Through or Pipeline mode; active low                                     |
| $\overline{\text{LBO}}$                                                                                                          | I    | Linear Burst Order mode; active low                                           |
| V <sub>DD</sub>                                                                                                                  | I    | Core power supply                                                             |
| V <sub>SS</sub>                                                                                                                  | I    | I/O and Core Ground                                                           |
| V <sub>DDQ</sub>                                                                                                                 | I    | Output driver power supply                                                    |

## 165 Bump BGA—x18 Commom I/O—Top View (Package D)

|   | 1                | 2   | 3               | 4               | 5               | 6               | 7               | 8                 | 9                 | 10  | 11  |   |
|---|------------------|-----|-----------------|-----------------|-----------------|-----------------|-----------------|-------------------|-------------------|-----|-----|---|
| A | NC               | A   | $\overline{E1}$ | $\overline{BB}$ | NC              | $\overline{E3}$ | $\overline{BW}$ | $\overline{ADSC}$ | $\overline{ADV}$  | A   | A   | A |
| B | NC               | A   | E2              | NC              | $\overline{BA}$ | CK              | $\overline{GW}$ | $\overline{G}$    | $\overline{ADSP}$ | A   | NC  | B |
| C | NC               | NC  | $V_{DDQ}$       | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$          | $V_{DDQ}$         | NC  | DQA | C |
| D | NC               | DQB | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | NC  | DQA | D |
| E | NC               | DQB | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | NC  | DQA | E |
| F | NC               | DQB | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | NC  | DQA | F |
| G | NC               | DQB | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | NC  | DQA | G |
| H | $\overline{FT}$  | MCL | NC              | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | NC                | NC  | ZZ  | H |
| J | DQB              | NC  | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | NC  | J |
| K | DQB              | NC  | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | NC  | K |
| L | DQB              | NC  | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | NC  | L |
| M | DQB              | NC  | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | NC  | M |
| N | DQB              | NC  | $V_{DDQ}$       | $V_{SS}$        | NC              | NC              | NC              | $V_{SS}$          | $V_{DDQ}$         | NC  | NC  | N |
| P | NC               | NC  | A               | A               | TDI             | A1              | TDO             | A                 | A                 | A   | A   | P |
| R | $\overline{LBO}$ | NC  | A               | A               | TMS             | A0              | TCK             | A                 | A                 | A   | A   | R |

11 x 15 Bump BGA—13mm x 15 mm Body—1.0 mm Bump Pitch

## 165 Bump BGA—x32 Common I/O—Top View (Package D)

|   | 1                | 2   | 3               | 4               | 5               | 6               | 7               | 8                 | 9                 | 10  | 11  |   |
|---|------------------|-----|-----------------|-----------------|-----------------|-----------------|-----------------|-------------------|-------------------|-----|-----|---|
| A | NC               | A   | $\overline{E1}$ | $\overline{BC}$ | $\overline{BB}$ | $\overline{E3}$ | $\overline{BW}$ | $\overline{ADSC}$ | $\overline{ADV}$  | A   | NC  | A |
| B | NC               | A   | E2              | $\overline{BD}$ | $\overline{BA}$ | CK              | $\overline{GW}$ | $\overline{G}$    | $\overline{ADSP}$ | A   | NC  | B |
| C | NC               | NC  | $V_{DDQ}$       | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$          | $V_{DDQ}$         | NC  | NC  | C |
| D | DQC              | DQC | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQB | DQB | D |
| E | DQC              | DQC | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQB | DQB | E |
| F | DQC              | DQC | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQB | DQB | F |
| G | DQC              | DQC | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQB | DQB | G |
| H | $\overline{FT}$  | MCL | NC              | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | NC                | NC  | ZZ  | H |
| J | DQD              | DQD | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | DQA | J |
| K | DQD              | DQD | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | DQA | K |
| L | DQD              | DQD | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | DQA | L |
| M | DQD              | DQD | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | DQA | M |
| N | NC               | NC  | $V_{DDQ}$       | $V_{SS}$        | NC              | NC              | NC              | $V_{SS}$          | $V_{DDQ}$         | NC  | NC  | N |
| P | NC               | NC  | A               | A               | TDI             | A1              | TDO             | A                 | A                 | A   | A   | P |
| R | $\overline{LBO}$ | NC  | A               | A               | TMS             | A0              | TCK             | A                 | A                 | A   | A   | R |

11 x 15 Bump BGA—13mm x 15 mm Body—1.0 mm Bump Pitch

## 165 Bump BGA—x36 Common I/O—Top View (Package D)

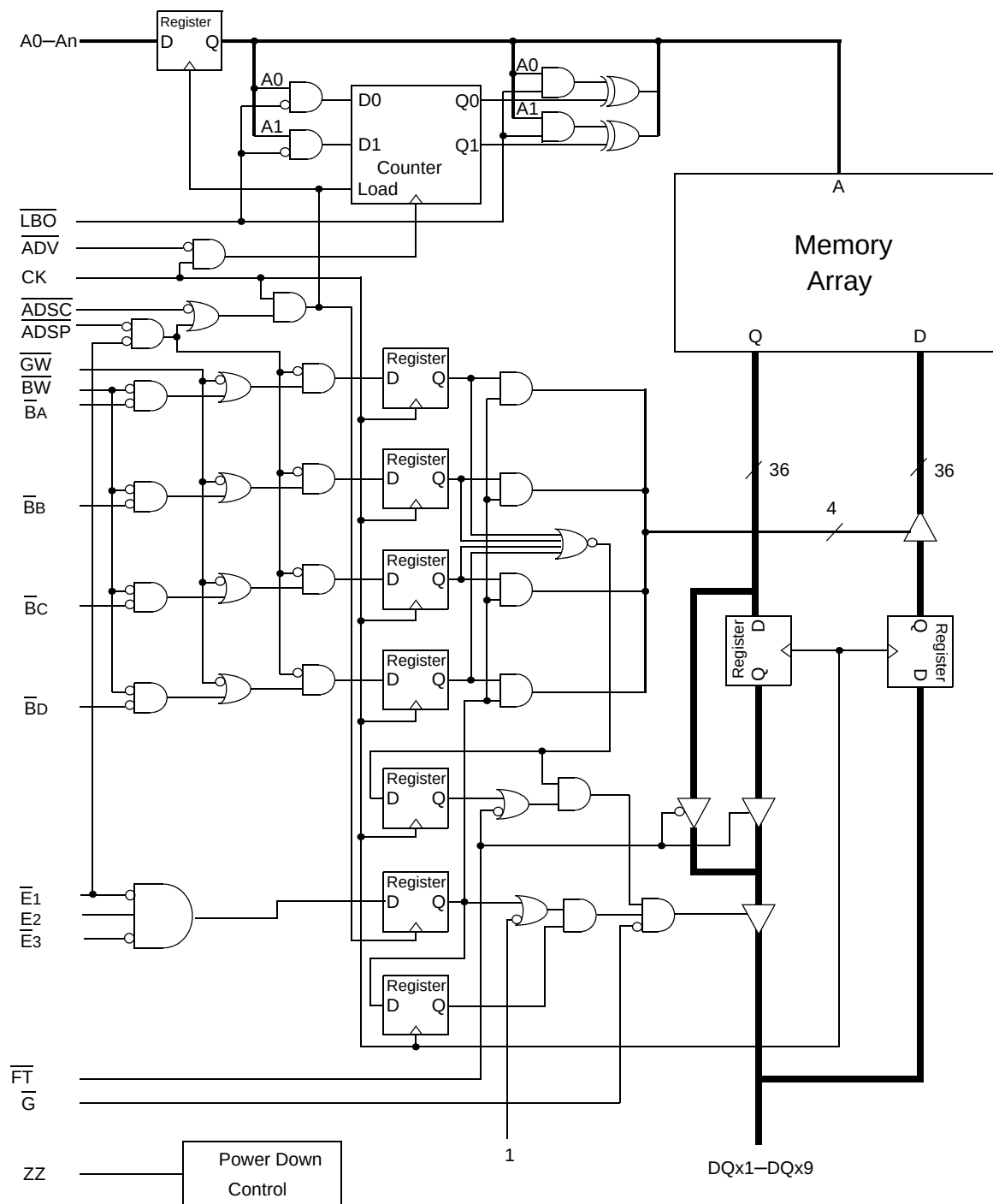
|   | 1                | 2   | 3               | 4               | 5               | 6               | 7               | 8                 | 9                 | 10  | 11   |   |
|---|------------------|-----|-----------------|-----------------|-----------------|-----------------|-----------------|-------------------|-------------------|-----|------|---|
| A | NC               | A   | $\overline{E1}$ | $\overline{BC}$ | $\overline{BB}$ | $\overline{E3}$ | $\overline{BW}$ | $\overline{ADSC}$ | $\overline{ADV}$  | A   | NC   | A |
| B | NC               | A   | E2              | $\overline{BD}$ | $\overline{BA}$ | CK              | $\overline{GW}$ | $\overline{G}$    | $\overline{ADSP}$ | A   | NC   | B |
| C | DQPC             | NC  | $V_{DDQ}$       | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$          | $V_{DDQ}$         | NC  | DQPB | C |
| D | DQC              | DQC | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQB | DQB  | D |
| E | DQC              | DQC | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQB | DQB  | E |
| F | DQC              | DQC | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQB | DQB  | F |
| G | DQC              | DQC | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQB | DQB  | G |
| H | $\overline{FT}$  | MCL | NC              | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | NC                | NC  | ZZ   | H |
| J | DQD              | DQD | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | DQA  | J |
| K | DQD              | DQD | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | DQA  | K |
| L | DQD              | DQD | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | DQA  | L |
| M | DQD              | DQD | $V_{DDQ}$       | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$          | $V_{DDQ}$         | DQA | DQA  | M |
| N | DQPD             | NC  | $V_{DDQ}$       | $V_{SS}$        | NC              | NC              | NC              | $V_{SS}$          | $V_{DDQ}$         | NC  | DQPA | N |
| P | NC               | NC  | A               | A               | TDI             | A1              | TDO             | A                 | A                 | A   | A    | P |
| R | $\overline{LBO}$ | NC  | A               | A               | TMS             | A0              | TCK             | A                 | A                 | A   | A    | R |

11 x 15 Bump BGA—13mm x 15 mm Body—1.0 mm Bump Pitch

## 165-Bump BGA Pin Description

| Symbol                                                                    | Type | Description                                                                                                  |
|---------------------------------------------------------------------------|------|--------------------------------------------------------------------------------------------------------------|
| A <sub>0</sub> , A <sub>1</sub>                                           | I    | Address field LSBs and Address Counter Preset Inputs                                                         |
| A                                                                         | I    | Address Inputs                                                                                               |
| DQ <sub>A</sub><br>DQ <sub>B</sub><br>DQ <sub>C</sub><br>DQ <sub>D</sub>  | I/O  | Data Input and Output pins                                                                                   |
| $\overline{B_A}$ , $\overline{B_B}$ , $\overline{B_C}$ , $\overline{B_D}$ | I    | Byte Write Enable for DQ <sub>A</sub> , DQ <sub>B</sub> , DQ <sub>C</sub> , DQ <sub>D</sub> I/Os; active low |
| NC                                                                        | —    | No Connect                                                                                                   |
| CK                                                                        | I    | Clock Input Signal; active high                                                                              |
| $\overline{BW}$                                                           | I    | Byte Write—Writes all enabled bytes; active low                                                              |
| $\overline{GW}$                                                           | I    | Global Write Enable—Writes all bytes; active low                                                             |
| $\overline{E_1}$                                                          | I    | Chip Enable; active low                                                                                      |
| $\overline{E_3}$                                                          | I    | Chip Enable; active low                                                                                      |
| E <sub>2</sub>                                                            | I    | Chip Enable; active high                                                                                     |
| $\overline{G}$                                                            | I    | Output Enable; active low                                                                                    |
| $\overline{ADV}$                                                          | I    | Burst address counter advance enable; active low                                                             |
| $\overline{ADSC}$ , $\overline{ADSP}$                                     | I    | Address Strobe (Processor, Cache Controller); active low                                                     |
| ZZ                                                                        | I    | Sleep mode control; active high                                                                              |
| $\overline{FT}$                                                           | I    | Flow Through or Pipeline mode; active low                                                                    |
| $\overline{LBO}$                                                          | I    | Linear Burst Order mode; active low                                                                          |
| TMS                                                                       | I    | Scan Test Mode Select                                                                                        |
| TDI                                                                       | I    | Scan Test Data In                                                                                            |
| TDO                                                                       | O    | Scan Test Data Out                                                                                           |
| TCK                                                                       | I    | Scan Test Clock                                                                                              |
| MCL                                                                       | —    | Must Connect Low                                                                                             |
| V <sub>DD</sub>                                                           | I    | Core power supply                                                                                            |
| V <sub>SS</sub>                                                           | I    | I/O and Core Ground                                                                                          |
| V <sub>DDQ</sub>                                                          | I    | Output driver power supply                                                                                   |

## GS88118/32/36C(T/D)-xxxIV Block Diagram



Note: Only x36 version shown for simplicity.

## Mode Pin Functions

| Mode Name               | Pin Name                | State   | Function                   |
|-------------------------|-------------------------|---------|----------------------------|
| Burst Order Control     | $\overline{\text{LBO}}$ | L       | Linear Burst               |
|                         |                         | H       | Interleaved Burst          |
| Output Register Control | $\overline{\text{FT}}$  | L       | Flow Through               |
|                         |                         | H or NC | Pipeline                   |
| Power Down Control      | ZZ                      | L or NC | Active                     |
|                         |                         | H       | Standby, $I_{DD} = I_{SB}$ |

### Note:

There is a pull-up device on the  $\overline{\text{FT}}$  pin and a pull-down device on the ZZ pin, so this input pin can be unconnected and the chip will operate in the default states as specified in the above tables.

## Burst Counter Sequences

### Linear Burst Sequence

|             | A[1:0] | A[1:0] | A[1:0] | A[1:0] |
|-------------|--------|--------|--------|--------|
| 1st address | 00     | 01     | 10     | 11     |
| 2nd address | 01     | 10     | 11     | 00     |
| 3rd address | 10     | 11     | 00     | 01     |
| 4th address | 11     | 00     | 01     | 10     |

### Note:

The burst counter wraps to initial state on the 5th clock.

### Interleaved Burst Sequence

|             | A[1:0] | A[1:0] | A[1:0] | A[1:0] |
|-------------|--------|--------|--------|--------|
| 1st address | 00     | 01     | 10     | 11     |
| 2nd address | 01     | 00     | 11     | 10     |
| 3rd address | 10     | 11     | 00     | 01     |
| 4th address | 11     | 10     | 01     | 00     |

### Note:

The burst counter wraps to initial state on the 5th clock.

Byte Write Truth Table

| Function        | $\overline{GW}$ | $\overline{BW}$ | $\overline{BA}$ | $\overline{BB}$ | $\overline{BC}$ | $\overline{BD}$ | Notes   |
|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|---------|
| Read            | H               | H               | X               | X               | X               | X               | 1       |
| Write No Bytes  | H               | L               | H               | H               | H               | H               | 1       |
| Write byte a    | H               | L               | L               | H               | H               | H               | 2, 3    |
| Write byte b    | H               | L               | H               | L               | H               | H               | 2, 3    |
| Write byte c    | H               | L               | H               | H               | L               | H               | 2, 3, 4 |
| Write byte d    | H               | L               | H               | H               | H               | L               | 2, 3, 4 |
| Write all bytes | H               | L               | L               | L               | L               | L               | 2, 3, 4 |
| Write all bytes | L               | X               | X               | X               | X               | X               |         |

## Notes:

1. All byte outputs are active in read cycles regardless of the state of Byte Write Enable inputs,  $\overline{BA}$ ,  $\overline{BB}$ ,  $\overline{BC}$  and/or  $\overline{BD}$ .
2. Byte Write Enable inputs  $\overline{BA}$ ,  $\overline{BB}$ ,  $\overline{BC}$  and/or  $\overline{BD}$  may be used in any combination with  $\overline{BW}$  to write single or multiple bytes.
3. All byte I/Os remain High-Z during all write operations regardless of the state of Byte Write Enable inputs.
4. Bytes "c" and "d" are only available on the x32 and x36 versions.

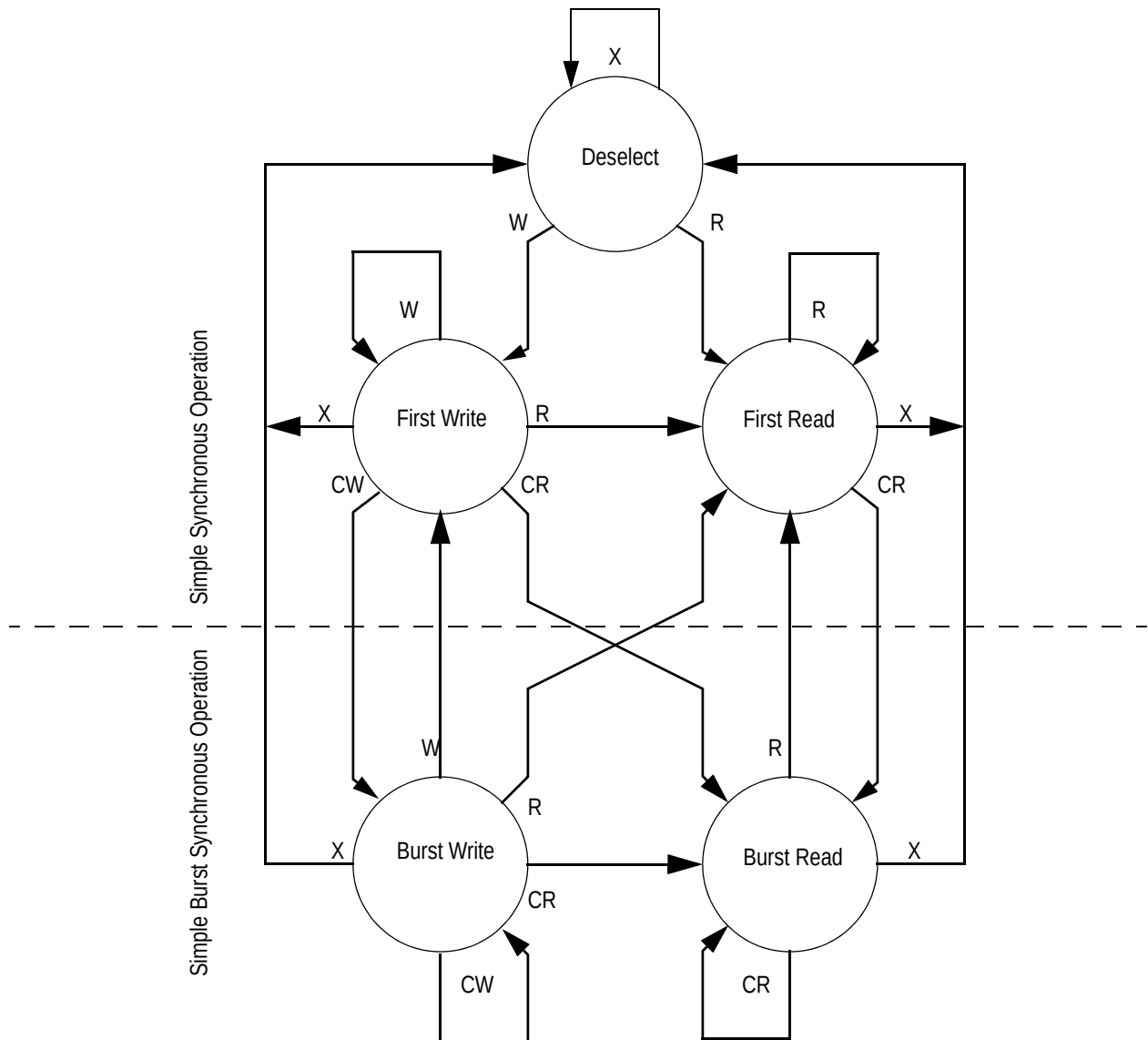
## Synchronous Truth Table

| Operation                          | Address Used | State Diagram Key | $\overline{E}_1$ | $E_2$ | $\overline{E}_3$ | $\overline{ADSP}$ | $\overline{ADSC}$ | $\overline{ADV}$ | $\overline{W}$ | DQ <sup>3</sup> |
|------------------------------------|--------------|-------------------|------------------|-------|------------------|-------------------|-------------------|------------------|----------------|-----------------|
| Deselect Cycle, Power Down         | None         | X                 | L                | X     | H                | X                 | L                 | X                | X              | High-Z          |
| Deselect Cycle, Power Down         | None         | X                 | L                | L     | X                | X                 | L                 | X                | X              | High-Z          |
| Deselect Cycle, Power Down         | None         | X                 | L                | X     | H                | L                 | X                 | X                | X              | High-Z          |
| Deselect Cycle, Power Down         | None         | X                 | L                | L     | X                | L                 | X                 | X                | X              | High-Z          |
| Deselect Cycle, Power Down         | None         | X                 | H                | X     | X                | X                 | L                 | X                | X              | High-Z          |
| Read Cycle, Begin Burst            | External     | R                 | L                | H     | L                | L                 | X                 | X                | X              | Q               |
| Read Cycle, Begin Burst            | External     | R                 | L                | H     | L                | H                 | L                 | X                | F              | Q               |
| Write Cycle, Begin Burst           | External     | W                 | L                | H     | L                | H                 | L                 | X                | T              | D               |
| <i>Read Cycle, Continue Burst</i>  | <i>Next</i>  | <i>CR</i>         | X                | X     | X                | <i>H</i>          | <i>H</i>          | <i>L</i>         | <i>F</i>       | <i>Q</i>        |
| Read Cycle, Continue Burst         | Next         | CR                | H                | X     | X                | X                 | H                 | L                | F              | Q               |
| <i>Write Cycle, Continue Burst</i> | <i>Next</i>  | <i>CW</i>         | X                | X     | X                | <i>H</i>          | <i>H</i>          | <i>L</i>         | <i>T</i>       | <i>D</i>        |
| Write Cycle, Continue Burst        | Next         | CW                | H                | X     | X                | X                 | H                 | L                | T              | D               |
| Read Cycle, Suspend Burst          | Current      |                   | X                | X     | X                | H                 | H                 | H                | F              | Q               |
| Read Cycle, Suspend Burst          | Current      |                   | H                | X     | X                | X                 | H                 | H                | F              | Q               |
| Write Cycle, Suspend Burst         | Current      |                   | X                | X     | X                | H                 | H                 | H                | T              | D               |
| Write Cycle, Suspend Burst         | Current      |                   | H                | X     | X                | X                 | H                 | H                | T              | D               |

### Notes:

1. X = Don't Care, H = High, L = Low
2.  $E = T$  (True) if  $E_2 = 1$  and  $\overline{E}_1 = \overline{E}_3 = 0$ ;  $E = F$  (False) if  $E_2 = 0$  or  $\overline{E}_1 = 1$  or  $\overline{E}_3 = 1$
3.  $W = T$  (True) and  $F$  (False) is defined in the Byte Write Truth Table preceding.
4.  $\overline{G}$  is an asynchronous input.  $\overline{G}$  can be driven high at any time to disable active output drivers.  $\overline{G}$  low can only enable active drivers (shown as "Q" in the Truth Table above).
5. All input combinations shown above are tested and supported. Input combinations shown in gray boxes need not be used to accomplish basic synchronous or synchronous burst operations and may be avoided for simplicity.
6. Tying  $\overline{ADSP}$  high and  $\overline{ADSC}$  low allows simple non-burst synchronous operations. See **BOLD** items above.
7. Tying  $\overline{ADSP}$  high and  $\overline{ADV}$  low while using  $\overline{ADSC}$  to load new addresses allows simple burst operations. See *ITALIC* items above.

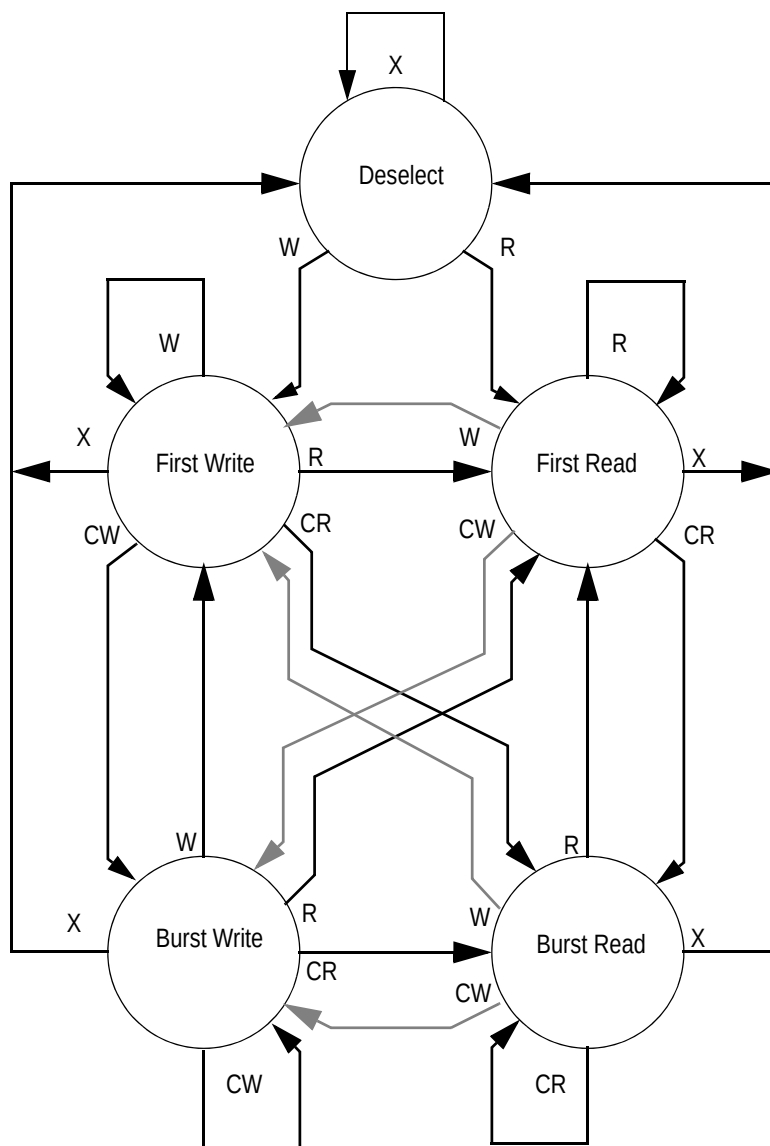
### Simplified State Diagram



#### Notes:

1. The diagram shows only supported (tested) synchronous state transitions. The diagram presumes  $\overline{G}$  is tied low.
2. The upper portion of the diagram assumes active use of only the Enable ( $\overline{E1}$ ) and Write ( $\overline{BA}$ ,  $\overline{BB}$ ,  $\overline{BC}$ ,  $\overline{BD}$ ,  $\overline{BW}$ , and  $\overline{GW}$ ) control inputs, and that  $\overline{ADSP}$  is tied high and  $\overline{ADSC}$  is tied low.
3. The upper and lower portions of the diagram together assume active use of only the Enable, Write, and  $\overline{ADSC}$  control inputs, and assumes  $\overline{ADSP}$  is tied high and  $\overline{ADV}$  is tied low.

# Simplified State Diagram with $\overline{G}$



## Notes:

1. The diagram shows supported (tested) synchronous state transitions plus supported transitions that depend upon the use of  $\overline{G}$ .
2. Use of "Dummy Reads" (Read Cycles with  $\overline{G}$  High) may be used to make the transition from read cycles to write cycles without passing through a deselect cycle. Dummy read cycles increment the address counter just like normal read cycles.
3. Transitions shown in gray tone assume  $\overline{G}$  has been pulsed high long enough to turn the RAM's drivers off and for incoming data to meet Data Input Set Up Time.

## Absolute Maximum Ratings

(All voltages reference to  $V_{SS}$ )

| Symbol     | Description                   | Value                                       | Unit |
|------------|-------------------------------|---------------------------------------------|------|
| $V_{DD}$   | Voltage on $V_{DD}$ Pins      | −0.5 to 4.6                                 | V    |
| $V_{DDQ}$  | Voltage on $V_{DDQ}$ Pins     | −0.5 to $V_{DD}$                            | V    |
| $V_{I/O}$  | Voltage on I/O Pins           | −0.5 to $V_{DD} + 0.5$ ( $\leq 4.6$ V max.) | V    |
| $V_{IN}$   | Voltage on Other Input Pins   | −0.5 to $V_{DD} + 0.5$ ( $\leq 4.6$ V max.) | V    |
| $I_{IN}$   | Input Current on Any Pin      | +/−20                                       | mA   |
| $I_{OUT}$  | Output Current on Any I/O Pin | +/−20                                       | mA   |
| $P_D$      | Package Power Dissipation     | 1.5                                         | W    |
| $T_{STG}$  | Storage Temperature           | −55 to 125                                  | °C   |
| $T_{BIAS}$ | Temperature Under Bias        | −55 to 125                                  | °C   |

### Notes:

Permanent damage to the device may occur if the Absolute Maximum Ratings are exceeded. Operation should be restricted to Recommended Operating Conditions. Exposure to conditions exceeding the Absolute Maximum Ratings, for an extended period of time, may affect reliability of this component.

## Power Supply Voltage Ranges

| Parameter                          | Symbol     | Min. | Typ. | Max. | Unit |
|------------------------------------|------------|------|------|------|------|
| 1.8 V Supply Voltage               | $V_{DD1}$  | 1.7  | 1.8  | 2.0  | V    |
| 2.5 V Supply Voltage               | $V_{DD2}$  | 2.3  | 2.5  | 2.7  | V    |
| 1.8 V $V_{DDQ}$ I/O Supply Voltage | $V_{DDQ1}$ | 1.7  | 1.8  | 2.0  | V    |
| 2.5 V $V_{DDQ}$ I/O Supply Voltage | $V_{DDQ2}$ | 2.3  | 2.5  | 2.7  | V    |

## Logic Levels

| Parameter                    | Symbol    | Min.               | Typ. | Max.               | Unit |
|------------------------------|-----------|--------------------|------|--------------------|------|
| $V_{DD}$ Input High Voltage  | $V_{IH}$  | $0.6 \cdot V_{DD}$ | —    | $V_{DD} + 0.3$     | V    |
| $V_{DD}$ Input Low Voltage   | $V_{IL}$  | −0.3               | —    | $0.3 \cdot V_{DD}$ | V    |
| $V_{DDQ}$ Input High Voltage | $V_{IHQ}$ | $0.6 \cdot V_{DD}$ | —    | $V_{DDQ} + 0.3$    | V    |
| $V_{DDQ}$ Input Low Voltage  | $V_{ILQ}$ | −0.3               | —    | $0.3 \cdot V_{DD}$ | V    |

### Note:

$V_{IHQ}$  (max) is voltage on  $V_{DDQ}$  pins plus 0.3 V.

## Recommended Operating Temperatures

| Parameter                                        | Symbol | Min. | Typ. | Max. | Unit |
|--------------------------------------------------|--------|------|------|------|------|
| Ambient Temperature (Industrial Range Versions)* | $T_A$  | -40  | 25   | 85   | °C   |

### Note:

The part numbers of Industrial Temperature Range versions end with the character "I". Unless otherwise noted, all performance specifications quoted are evaluated for worst case in the temperature range marked on the device.

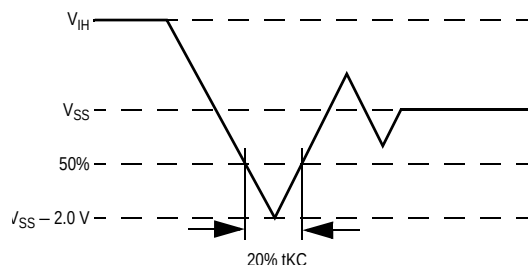
## Thermal Impedance

| Package  | Test PCB Substrate | $\theta_{JA}$ (C°/W)<br>Airflow = 0 m/s | $\theta_{JA}$ (C°/W)<br>Airflow = 1 m/s | $\theta_{JA}$ (C°/W)<br>Airflow = 2 m/s | $\theta_{JB}$ (C°/W) | $\theta_{JC}$ (C°/W) |
|----------|--------------------|-----------------------------------------|-----------------------------------------|-----------------------------------------|----------------------|----------------------|
| 100 TQFP | 4-layer            | 38.7                                    | 33.5                                    | 31.9                                    | 27.6                 | 10.6                 |
| 165 BGA  | 4-layer            | 27.4                                    | 24.2                                    | 23.2                                    | 15.3                 | 7.8                  |

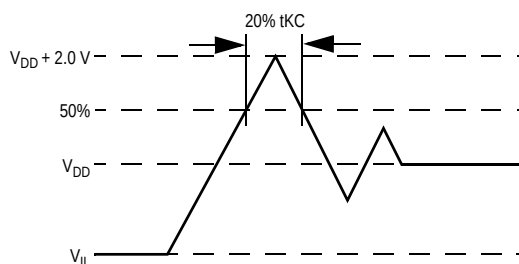
### Notes:

1. Thermal Impedance data is based on a number of samples from multiple lots and should be viewed as a typical number.
2. Please refer to JEDEC standard JESD51-6.
3. The characteristics of the test fixture PCB influence reported thermal characteristics of the device. Be advised that a good thermal path to the PCB can result in cooling or heating of the RAM depending on PCB temperature.

## Undershoot Measurement and Timing



## Overshoot Measurement and Timing



### Note:

Input Under/overshoot voltage must be  $-2\text{ V} > V_i < V_{DDn} + 2\text{ V}$  not to exceed 4.6 V maximum, with a pulse width not to exceed 20% tKC.

## Capacitance

( $T_A = 25^\circ\text{C}$ ,  $f = 1\text{ MHz}$ ,  $V_{DD} = 2.5\text{ V}$ )

| Parameter                | Symbol    | Test conditions        | Typ. | Max. | Unit |
|--------------------------|-----------|------------------------|------|------|------|
| Input Capacitance        | $C_{IN}$  | $V_{IN} = 0\text{ V}$  | 8    | 10   | pF   |
| Input/Output Capacitance | $C_{I/O}$ | $V_{OUT} = 0\text{ V}$ | 12   | 14   | pF   |

### Note:

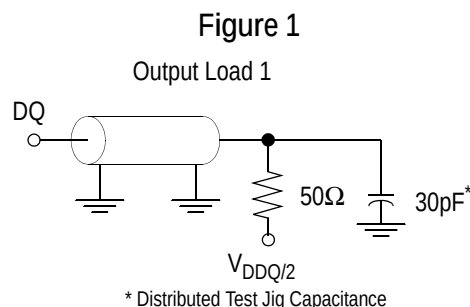
These parameters are sample tested.

## AC Test Conditions

| Parameter              | Conditions               |
|------------------------|--------------------------|
| Input high level       | $V_{DD} - 0.2 \text{ V}$ |
| Input low level        | $0.2 \text{ V}$          |
| Input slew rate        | $1 \text{ V/ns}$         |
| Input reference level  | $V_{DD}/2$               |
| Output reference level | $V_{DDQ}/2$              |
| Output load            | Fig. 1                   |

### Notes:

1. Include scope and jig capacitance.
2. Test conditions as specified with output loading as shown in Fig. 1 unless otherwise noted.
3. Device is deselected as defined by the Truth Table.



## DC Electrical Characteristics

| Parameter                                | Symbol    | Test Conditions                                        | Min                       | Max              |
|------------------------------------------|-----------|--------------------------------------------------------|---------------------------|------------------|
| Input Leakage Current (except mode pins) | $I_{IL}$  | $V_{IN} = 0 \text{ to } V_{DD}$                        | $-1 \text{ uA}$           | $1 \text{ uA}$   |
| $\overline{FT}$ Input Current            | $I_{IN}$  | $V_{DD} \geq V_{IN} \geq 0 \text{ V}$                  | $-100 \text{ uA}$         | $100 \text{ uA}$ |
| Output Leakage Current                   | $I_{OL}$  | Output Disable, $V_{OUT} = 0 \text{ to } V_{DD}$       | $-1 \text{ uA}$           | $1 \text{ uA}$   |
| 1.8 V Output High Voltage                | $V_{OH1}$ | $I_{OH} = -4 \text{ mA}$ , $V_{DDQ} = 1.7 \text{ V}$   | $V_{DDQ} - 0.4 \text{ V}$ | —                |
| 2.5 V Output High Voltage                | $V_{OH2}$ | $I_{OH} = -8 \text{ mA}$ , $V_{DDQ} = 2.375 \text{ V}$ | $1.7 \text{ V}$           | —                |
| 1.8 V Output Low Voltage                 | $V_{OL1}$ | $I_{OL} = 4 \text{ mA}$                                | —                         | $0.4 \text{ V}$  |
| 2.5 V Output Low Voltage                 | $V_{OL2}$ | $I_{OL} = 8 \text{ mA}$                                | —                         | $0.4 \text{ V}$  |

## Operating Currents

| Parameter         | Test Conditions                                                                       | Mode      | Symbol                                | -250I          | -200I          | -150I          | Unit |
|-------------------|---------------------------------------------------------------------------------------|-----------|---------------------------------------|----------------|----------------|----------------|------|
|                   |                                                                                       |           |                                       | -40<br>to 85°C | -40<br>to 85°C | -40<br>to 85°C |      |
| Operating Current | Device Selected;<br>All other inputs<br>$\geq V_{IH}$ or $\leq V_{IL}$<br>Output open | (x32/x36) | Pipeline<br>$I_{DD}$<br>$I_{DDQ}$     | 200<br>20      | 170<br>15      | 145<br>20      | mA   |
|                   |                                                                                       |           | Flow Through<br>$I_{DD}$<br>$I_{DDQ}$ | 160<br>15      | 145<br>15      | 130<br>15      | mA   |
|                   |                                                                                       | (x18)     | Pipeline<br>$I_{DD}$<br>$I_{DDQ}$     | 185<br>10      | 160<br>10      | 135<br>10      | mA   |
|                   |                                                                                       |           | Flow Through<br>$I_{DD}$<br>$I_{DDQ}$ | 145<br>10      | 125<br>10      | 125<br>8       | mA   |
| Standby Current   | $ZZ \geq V_{DD} - 0.2 V$                                                              | —         | Pipeline<br>$I_{SB}$                  | 45             | 45             | 45             | mA   |
|                   |                                                                                       |           | Flow Through<br>$I_{SB}$              | 45             | 45             | 45             | mA   |
| Deselect Current  | Device Deselected;<br>All other inputs<br>$\geq V_{IH}$ or $\leq V_{IL}$              | —         | Pipeline<br>$I_{DD}$                  | 65             | 65             | 60             | mA   |
|                   |                                                                                       |           | Flow Through<br>$I_{DD}$              | 60             | 60             | 60             | mA   |

### Notes:

- $I_{DD}$  and  $I_{DDQ}$  apply to any combination of  $V_{DD1}$ ,  $V_{DD2}$ ,  $V_{DDQ1}$ , and  $V_{DDQ2}$  operation.
- All parameters listed are worst case scenario.

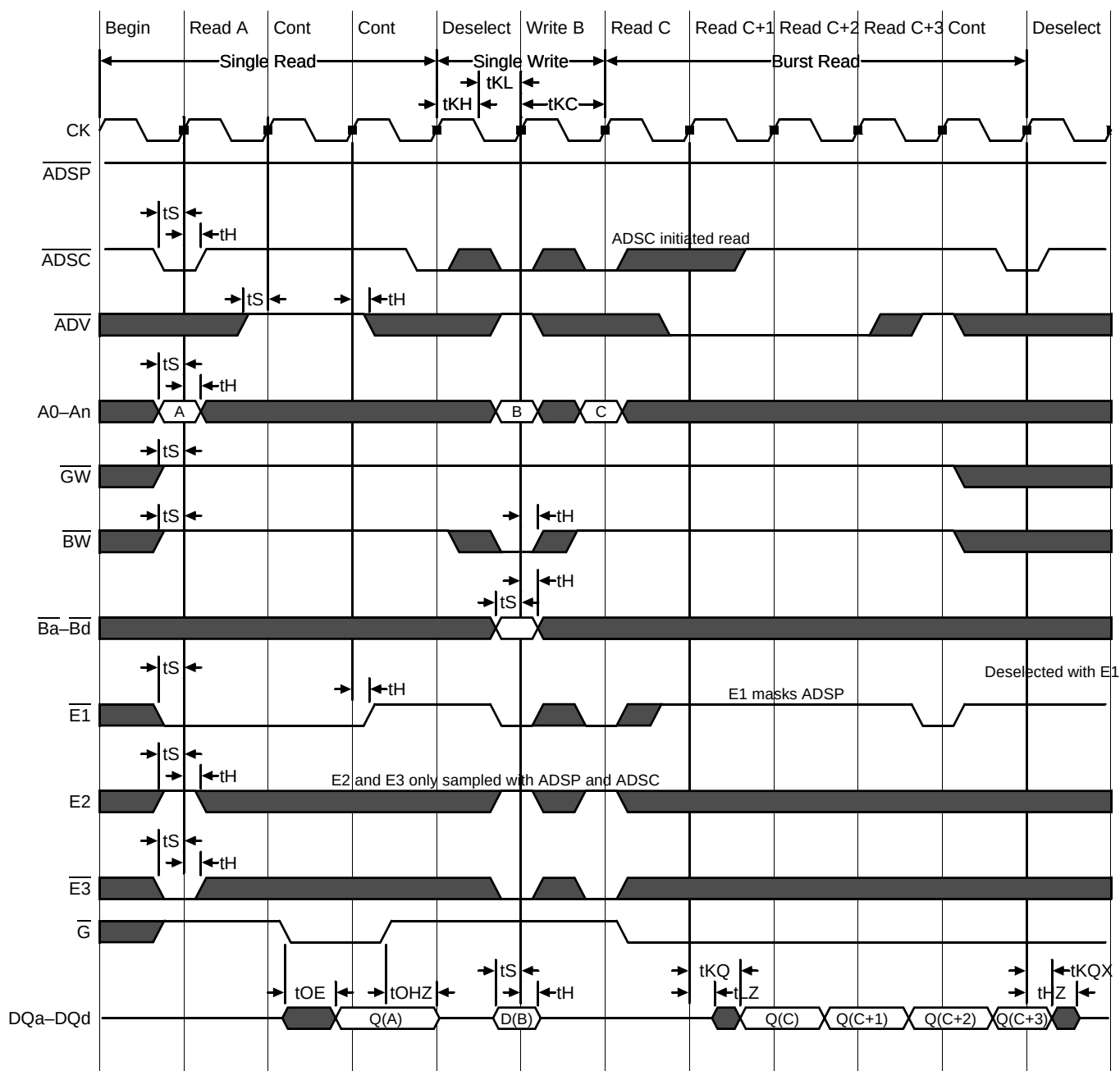
## AC Electrical Characteristics

|              | Parameter                          | Symbol                        | -250I |     | -200I |     | -150I |     | Unit |
|--------------|------------------------------------|-------------------------------|-------|-----|-------|-----|-------|-----|------|
|              |                                    |                               | Min   | Max | Min   | Max | Min   | Max |      |
| Pipeline     | Clock Cycle Time                   | t <sub>KC</sub>               | 4.0   | —   | 5.0   | —   | 6.7   | —   | ns   |
|              | Clock to Output Valid              | t <sub>KQ</sub>               | —     | 3.0 | —     | 3.0 | —     | 3.8 | ns   |
|              | Clock to Output Invalid            | t <sub>KQX</sub>              | 1.5   | —   | 1.5   | —   | 1.5   | —   | ns   |
|              | Clock to Output in Low-Z           | t <sub>LZ</sub> <sup>1</sup>  | 1.5   | —   | 1.5   | —   | 1.5   | —   | ns   |
|              | Setup time                         | t <sub>S</sub>                | 1.2   | —   | 1.4   | —   | 1.5   | —   | ns   |
|              | Hold time                          | t <sub>H</sub>                | 0.2   | —   | 0.4   | —   | 0.5   | —   | ns   |
| Flow Through | Clock Cycle Time                   | t <sub>KC</sub>               | 5.5   | —   | 6.5   | —   | 7.5   | —   | ns   |
|              | Clock to Output Valid              | t <sub>KQ</sub>               | —     | 5.5 | —     | 6.5 | —     | 7.5 | ns   |
|              | Clock to Output Invalid            | t <sub>KQX</sub>              | 2.0   | —   | 2.0   | —   | 2.0   | —   | ns   |
|              | Clock to Output in Low-Z           | t <sub>LZ</sub> <sup>1</sup>  | 2.0   | —   | 2.0   | —   | 2.0   | —   | ns   |
|              | Setup time                         | t <sub>S</sub>                | 1.5   | —   | 1.5   | —   | 1.5   | —   | ns   |
|              | Hold time                          | t <sub>H</sub>                | 0.5   | —   | 0.5   | —   | 0.5   | —   | ns   |
|              | Clock HIGH Time                    | t <sub>KH</sub>               | 1.3   | —   | 1.3   | —   | 1.5   | —   | ns   |
|              | Clock LOW Time                     | t <sub>KL</sub>               | 1.7   | —   | 1.7   | —   | 1.7   | —   | ns   |
|              | Clock to Output in High-Z          | t <sub>HZ</sub> <sup>1</sup>  | 1.5   | 2.5 | 1.5   | 3.0 | 1.5   | 3.0 | ns   |
|              | $\overline{G}$ to Output Valid     | t <sub>OE</sub>               | —     | 2.5 | —     | 3.0 | —     | 3.8 | ns   |
|              | $\overline{G}$ to output in Low-Z  | t <sub>OLZ</sub> <sup>1</sup> | 0     | —   | 0     | —   | 0     | —   | ns   |
|              | $\overline{G}$ to output in High-Z | t <sub>OHZ</sub> <sup>1</sup> | —     | 2.5 | —     | 3.0 | —     | 3.8 | ns   |
|              | ZZ setup time                      | t <sub>ZZS</sub> <sup>2</sup> | 5     | —   | 5     | —   | 5     | —   | ns   |
|              | ZZ hold time                       | t <sub>ZZH</sub> <sup>2</sup> | 1     | —   | 1     | —   | 1     | —   | ns   |
|              | ZZ recovery                        | t <sub>ZZR</sub>              | 20    | —   | 20    | —   | 20    | —   | ns   |

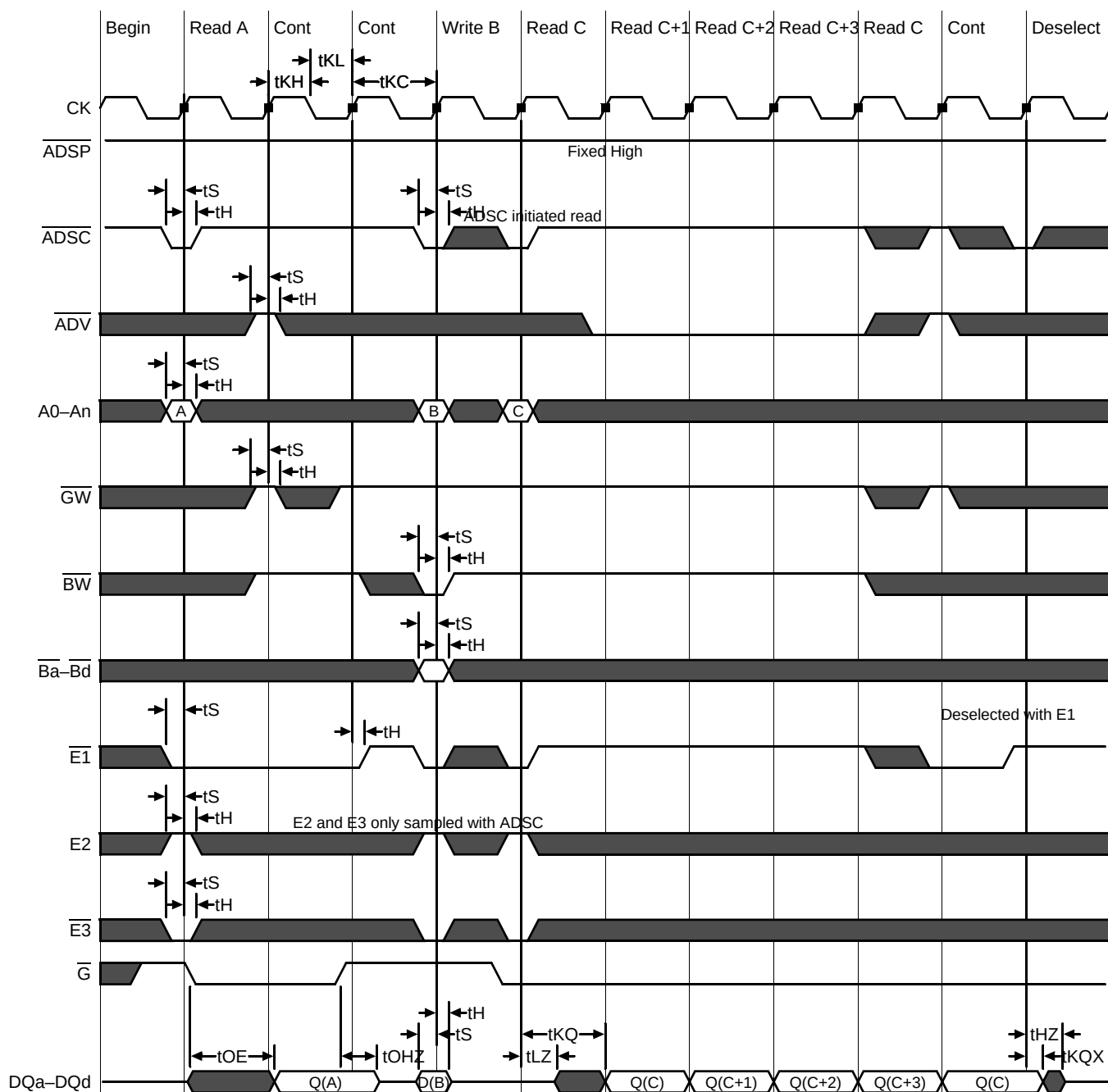
### Notes:

- These parameters are sampled and are not 100% tested
- ZZ is an asynchronous signal. However, In order to be recognized on any given clock cycle, ZZ must meet the specified setup and hold times as specified above.

# Pipeline Mode Timing



# Flow Through Mode Timing

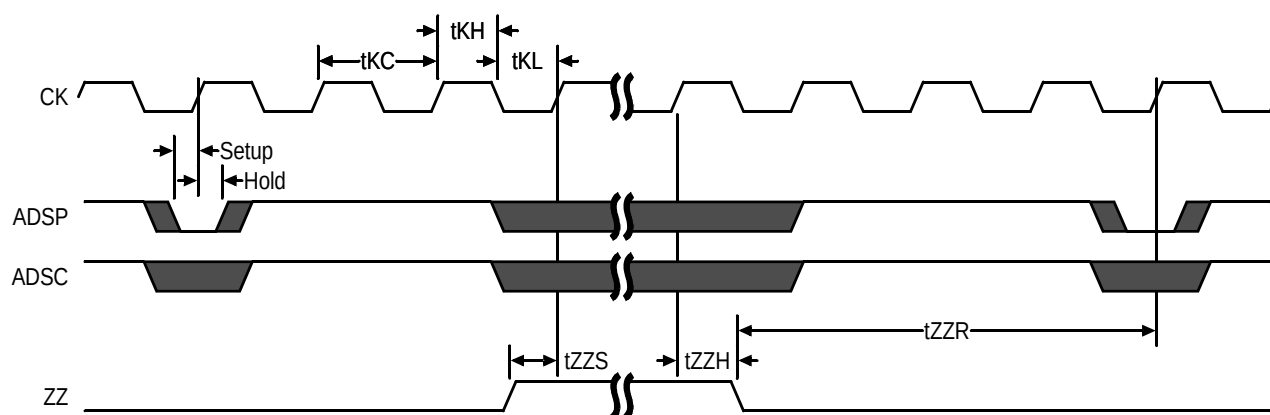


## Sleep Mode

During normal operation, ZZ must be pulled low, either by the user or by its internal pull down resistor. When ZZ is pulled high, the SRAM will enter a Power Sleep mode after 2 cycles. At this time, internal state of the SRAM is preserved. When ZZ returns to low, the SRAM operates normally after ZZ recovery time.

Sleep mode is a low current, power-down mode in which the device is deselected and current is reduced to  $I_{SB2}$ . The duration of Sleep mode is dictated by the length of time the ZZ is in a High state. After entering Sleep mode, all inputs except ZZ become disabled and all outputs go to High-Z. The ZZ pin is an asynchronous, active high input that causes the device to enter Sleep mode. When the ZZ pin is driven high,  $I_{SB2}$  is guaranteed after the time  $t_{ZZI}$  is met. Because ZZ is an asynchronous input, pending operations or operations in progress may not be properly completed if ZZ is asserted. Therefore, Sleep mode must not be initiated until valid pending operations are completed. Similarly, when exiting Sleep mode during  $t_{ZZR}$ , only a Deselect or Read commands may be applied while the SRAM is recovering from Sleep mode.

Sleep Mode Timing Diagram



## Application Tips

### Single and Dual Cycle Deselect

SCD devices (like this one) force the use of “dummy read cycles” (read cycles that are launched normally but that are ended with the output drivers inactive) in a fully synchronous environment. Dummy read cycles waste performance but their use usually assures there will be no bus contention in transitions from reads to writes or between banks of RAMs. DCD SRAMs do not waste bandwidth on dummy cycles and are logically simpler to manage in a multiple bank application (wait states need not be inserted at bank address boundary crossings) but greater care must be exercised to avoid excessive bus contention.

## JTAG Port Operation

### Overview

The JTAG Port on this RAM operates in a manner that is compliant with IEEE Standard 1149.1-1990, a serial boundary scan interface standard (commonly referred to as JTAG). The JTAG Port input interface levels scale with  $V_{DD}$ . The JTAG output drivers are powered by  $V_{DDQ}$ .

### Disabling the JTAG Port

It is possible to use this device without utilizing the JTAG port. The port is reset at power-up and will remain inactive unless clocked. TCK, TDI, and TMS are designed with internal pull-up circuits. To assure normal operation of the RAM with the JTAG Port unused, TCK, TDI, and TMS may be left floating or tied to either  $V_{DD}$  or  $V_{SS}$ . TDO should be left unconnected.

## JTAG Pin Descriptions

| Pin | Pin Name         | I/O | Description                                                                                                                                                                                                                                                                                                                                                                                                                                  |
|-----|------------------|-----|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| TCK | Test Clock       | In  | Clocks all TAP events. All inputs are captured on the rising edge of TCK and all outputs propagate from the falling edge of TCK.                                                                                                                                                                                                                                                                                                             |
| TMS | Test Mode Select | In  | The TMS input is sampled on the rising edge of TCK. This is the command input for the TAP controller state machine. An undriven TMS input will produce the same result as a logic one input level.                                                                                                                                                                                                                                           |
| TDI | Test Data In     | In  | The TDI input is sampled on the rising edge of TCK. This is the input side of the serial registers placed between TDI and TDO. The register placed between TDI and TDO is determined by the state of the TAP Controller state machine and the instruction that is currently loaded in the TAP Instruction Register (refer to the TAP Controller State Diagram). An undriven TDI pin will produce the same result as a logic one input level. |
| TDO | Test Data Out    | Out | Output that is active depending on the state of the TAP state machine. Output changes in response to the falling edge of TCK. This is the output side of the serial registers placed between TDI and TDO.                                                                                                                                                                                                                                    |

### Note:

This device does not have a TRST (TAP Reset) pin. TRST is optional in IEEE 1149.1. The Test-Logic-Reset state is entered while TMS is held high for five rising edges of TCK. The TAP Controller is also reset automatically at power-up.

## JTAG Port Registers

### Overview

The various JTAG registers, referred to as Test Access Port or TAP Registers, are selected (one at a time) via the sequences of 1s and 0s applied to TMS as TCK is strobed. Each of the TAP Registers is a serial shift register that captures serial input data on the rising edge of TCK and pushes serial data out on the next falling edge of TCK. When a register is selected, it is placed between the TDI and TDO pins.

### Instruction Register

The Instruction Register holds the instructions that are executed by the TAP controller when it is moved into the Run, Test/Idle, or the various data register states. Instructions are 3 bits long. The Instruction Register can be loaded when it is placed between the TDI and TDO pins. The Instruction Register is automatically preloaded with the IDCODE instruction at power-up or whenever the controller is placed in Test-Logic-Reset state.

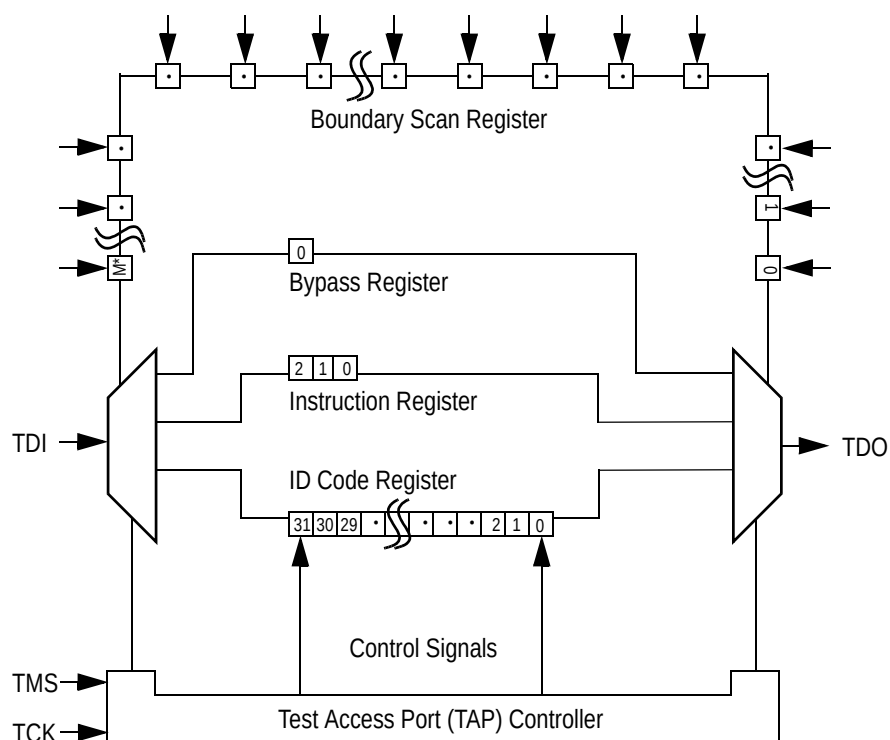
### Bypass Register

The Bypass Register is a single bit register that can be placed between TDI and TDO. It allows serial test data to be passed through the RAM's JTAG Port to another device in the scan chain with as little delay as possible.

### Boundary Scan Register

The Boundary Scan Register is a collection of flip flops that can be preset by the logic level found on the RAM's input or I/O pins. The flip flops are then daisy chained together so the levels found can be shifted serially out of the JTAG Port's TDO pin. The Boundary Scan Register also includes a number of place holder flip flops (always set to a logic 1). The relationship between the device pins and the bits in the Boundary Scan Register is described in the Scan Order Table following. The Boundary Scan Register, under the control of the TAP Controller, is loaded with the contents of the RAMs I/O ring when the controller is in Capture-DR state and then is placed between the TDI and TDO pins when the controller is moved to Shift-DR state. SAMPLE-Z, SAMPLE/PRELOAD and EXTEST instructions can be used to activate the Boundary Scan Register.

## JTAG TAP Block Diagram



\* For the value of M, see the BSDL file, which is available at by contacting us at [apps@gsitechnology.com](mailto:apps@gsitechnology.com).

### Identification (ID) Register

The ID Register is a 32-bit register that is loaded with a device and vendor specific 32-bit code when the controller is put in Capture-DR state with the IDCODE command loaded in the Instruction Register. The code is loaded from a 32-bit on-chip ROM. It describes various attributes of the RAM as indicated below. The register is then placed between the TDI and TDO pins when the controller is moved into Shift-DR state. Bit 0 in the register is the LSB and the first to reach TDO when shifting begins.

### ID Register Contents

|       |          |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |                                           |    |   |   |   |   |   |   |   |   |                   |   |
|-------|----------|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|-------------------------------------------|----|---|---|---|---|---|---|---|---|-------------------|---|
|       | Not Used |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    | GSI Technology<br>JEDEC Vendor<br>ID Code |    |   |   |   |   |   |   |   |   | Presence Register |   |
| Bit # | 31       | 30 | 29 | 28 | 27 | 26 | 25 | 24 | 23 | 22 | 21 | 20 | 19 | 18 | 17 | 16 | 15 | 14 | 13 | 12 | 11                                        | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1                 | 0 |
|       | X        | X  | X  | X  | X  | X  | X  | X  | X  | X  | X  | X  | X  | X  | X  | X  | X  | X  | X  | X  | 0                                         | 0  | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 1                 | 1 |

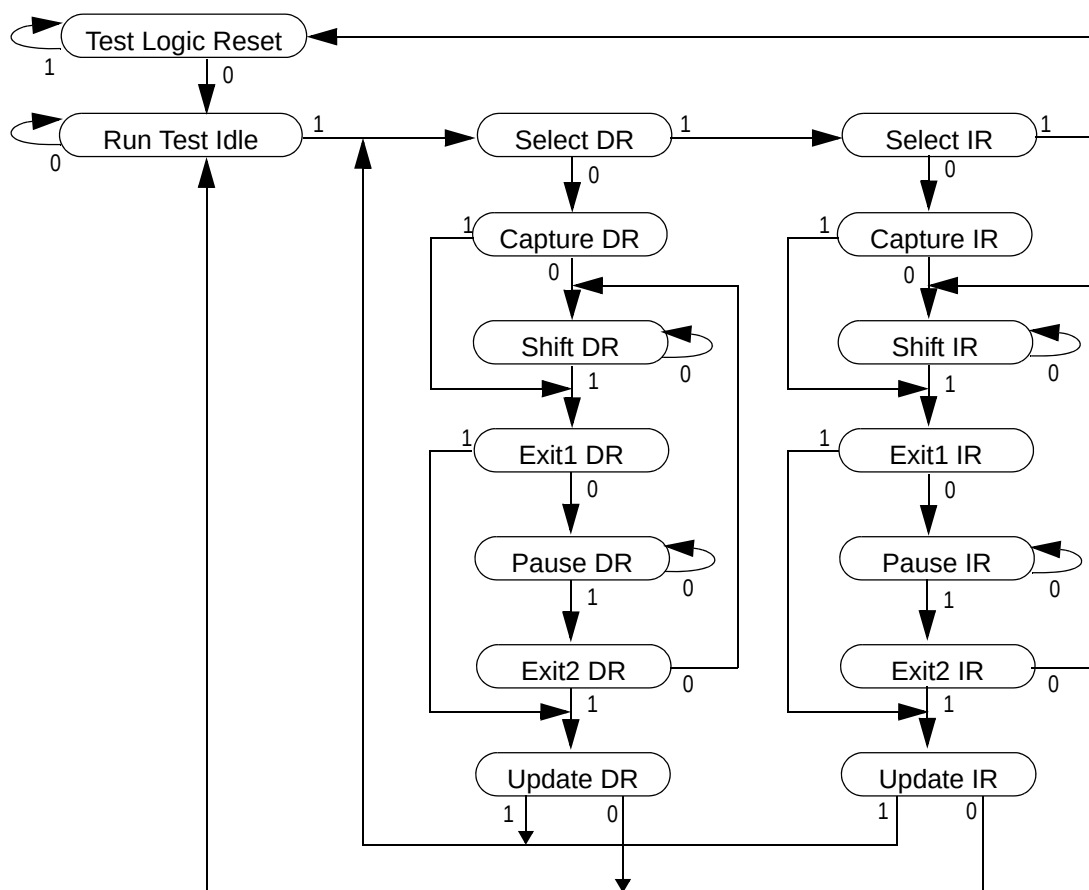
## Tap Controller Instruction Set

### Overview

There are two classes of instructions defined in the Standard 1149.1-1990; the standard (Public) instructions, and device specific (Private) instructions. Some Public instructions are mandatory for 1149.1 compliance. Optional Public instructions must be implemented in prescribed ways. The TAP on this device may be used to monitor all input and I/O pads, and can be used to load address, data or control signals into the RAM or to preload the I/O buffers.

When the TAP controller is placed in Capture-IR state the two least significant bits of the instruction register are loaded with 01. When the controller is moved to the Shift-IR state the Instruction Register is placed between TDI and TDO. In this state the desired instruction is serially loaded through the TDI input (while the previous contents are shifted out at TDO). For all instructions, the TAP executes newly loaded instructions only when the controller is moved to Update-IR state. The TAP instruction set for this device is listed in the following table.

JTAG Tap Controller State Diagram



### Instruction Descriptions

#### BYPASS

When the BYPASS instruction is loaded in the Instruction Register the Bypass Register is placed between TDI and TDO. This occurs when the TAP controller is moved to the Shift-DR state. This allows the board level scan path to be shortened to facilitate testing of other devices in the scan path.

#### SAMPLE/PRELOAD

SAMPLE/PRELOAD is a Standard 1149.1 mandatory public instruction. When the SAMPLE / PRELOAD instruction is loaded in the Instruction Register, moving the TAP controller into the Capture-DR state loads the data in the RAMs input and I/O buffers into the Boundary Scan Register. Boundary Scan Register locations are not associated with an input or I/O pin, and are loaded with the default state identified in the Boundary Scan Chain table at the end of this section of the datasheet. Because the RAM clock is independent from the TAP Clock (TCK) it is possible for the TAP to attempt to capture the I/O ring contents while the input buffers are in transition (i.e. in a metastable state). Although allowing the TAP to sample metastable inputs will not harm the device, repeatable results cannot be expected. RAM input signals must be stabilized for long enough to meet the TAPs input data capture set-up plus hold time ( $t_{TS}$  plus  $t_{TH}$ ). The RAMs clock inputs need not be paused for any other TAP operation except capturing the I/O ring contents into the Boundary Scan Register. Moving the controller to Shift-DR state then places the boundary scan register between the TDI and TDO pins.

#### EXTEST

EXTEST is an IEEE 1149.1 mandatory public instruction. It is to be executed whenever the instruction register is loaded with all logic 0s. The EXTEST command does not block or override the RAM's input pins; therefore, the RAM's internal state is still determined by its input pins.

Typically, the Boundary Scan Register is loaded with the desired pattern of data with the SAMPLE/PRELOAD command. Then the EXTEST command is used to output the Boundary Scan Register's contents, in parallel, on the RAM's data output drivers on the falling edge of TCK when the controller is in the Update-IR state.

Alternately, the Boundary Scan Register may be loaded in parallel using the EXTEST command. When the EXTEST instruction is selected, the state of all the RAM's input and I/O pins, as well as the default values at Scan Register locations not associated with a pin, are transferred in parallel into the Boundary Scan Register on the rising edge of TCK in the Capture-DR state, the RAM's output pins drive out the value of the Boundary Scan Register location with which each output pin is associated.

#### IDCODE

The IDCODE instruction causes the ID ROM to be loaded into the ID register when the controller is in Capture-DR mode and places the ID register between the TDI and TDO pins in Shift-DR mode. The IDCODE instruction is the default instruction loaded in at power up and any time the controller is placed in the Test-Logic-Reset state.

#### SAMPLE-Z

If the SAMPLE-Z instruction is loaded in the instruction register, all RAM outputs are forced to an inactive drive state (high-Z) and the Boundary Scan Register is connected between TDI and TDO when the TAP controller is moved to the Shift-DR state.

#### RFU

These instructions are Reserved for Future Use. In this device they replicate the BYPASS instruction.

## JTAG TAP Instruction Set Summary

| Instruction        | Code | Description                                                                                                                         | Notes |
|--------------------|------|-------------------------------------------------------------------------------------------------------------------------------------|-------|
| EXTEST             | 000  | Places the Boundary Scan Register between TDI and TDO.                                                                              | 1     |
| IDCODE             | 001  | Preloads ID Register and places it between TDI and TDO.                                                                             | 1, 2  |
| SAMPLE-Z           | 010  | Captures I/O ring contents. Places the Boundary Scan Register between TDI and TDO.<br>Forces all RAM output drivers to High-Z.      | 1     |
| RFU                | 011  | Do not use this instruction; Reserved for Future Use.<br>Replicates BYPASS instruction. Places Bypass Register between TDI and TDO. | 1     |
| SAMPLE/<br>PRELOAD | 100  | Captures I/O ring contents. Places the Boundary Scan Register between TDI and TDO.                                                  | 1     |
| GSI                | 101  | GSI private instruction.                                                                                                            | 1     |
| RFU                | 110  | Do not use this instruction; Reserved for Future Use.<br>Replicates BYPASS instruction. Places Bypass Register between TDI and TDO. | 1     |
| BYPASS             | 111  | Places Bypass Register between TDI and TDO.                                                                                         | 1     |

### Notes:

1. Instruction codes expressed in binary, MSB on left, LSB on right.
2. Default instruction automatically loaded at power-up and in test-logic-reset state.

## JTAG Port Recommended Operating Conditions and DC Characteristics (1.8/2.5 V Version)

| Parameter                              | Symbol     | Min.                       | Max.            | Unit | Notes |
|----------------------------------------|------------|----------------------------|-----------------|------|-------|
| 1.8 V Test Port Input Low Voltage      | $V_{ILJ1}$ | -0.3                       | $0.3 * V_{DD1}$ | V    | 1     |
| 2.5 V Test Port Input Low Voltage      | $V_{ILJ2}$ | -0.3                       | $0.3 * V_{DD2}$ | V    | 1     |
| 1.8 V Test Port Input High Voltage     | $V_{IHJ1}$ | $0.6 * V_{DD1}$            | $V_{DD1} + 0.3$ | V    | 1     |
| 2.5 V Test Port Input High Voltage     | $V_{IHJ2}$ | $0.6 * V_{DD2}$            | $V_{DD2} + 0.3$ | V    | 1     |
| TMS, TCK and TDI Input Leakage Current | $I_{INHJ}$ | -300                       | 1               | uA   | 2     |
| TMS, TCK and TDI Input Leakage Current | $I_{INLJ}$ | -1                         | 100             | uA   | 3     |
| TDO Output Leakage Current             | $I_{OLJ}$  | -1                         | 1               | uA   | 4     |
| Test Port Output High Voltage          | $V_{OHJ}$  | 1.7                        | —               | V    | 5, 6  |
| Test Port Output Low Voltage           | $V_{OLJ}$  | —                          | 0.4             | V    | 5, 7  |
| Test Port Output CMOS High             | $V_{OHJC}$ | $V_{DDQ} - 100 \text{ mV}$ | —               | V    | 5, 8  |
| Test Port Output CMOS Low              | $V_{OLJC}$ | —                          | 100 mV          | V    | 5, 9  |

### Notes:

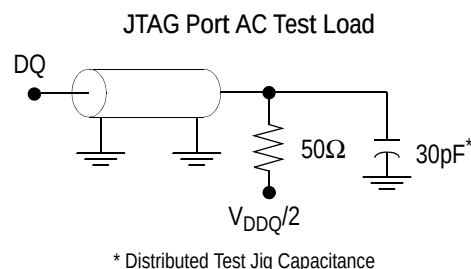
- Input Under/overshoot voltage must be  $-2 \text{ V} < V_i < V_{DDn} + 2 \text{ V}$  not to exceed 4.6 V maximum, with a pulse width not to exceed 20% tTKC.
- $V_{ILJ} \leq V_{IN} \leq V_{DDn}$
- $0 \text{ V} \leq V_{IN} \leq V_{ILJn}$
- Output Disable,  $V_{OUT} = 0 \text{ to } V_{DDn}$
- The TDO output driver is served by the  $V_{DDQ}$  supply.
- $I_{OHJ} = -4 \text{ mA}$
- $I_{OLJ} = +4 \text{ mA}$
- $I_{OHJC} = -100 \text{ uA}$
- $I_{OLJC} = +100 \text{ uA}$

## JTAG Port AC Test Conditions

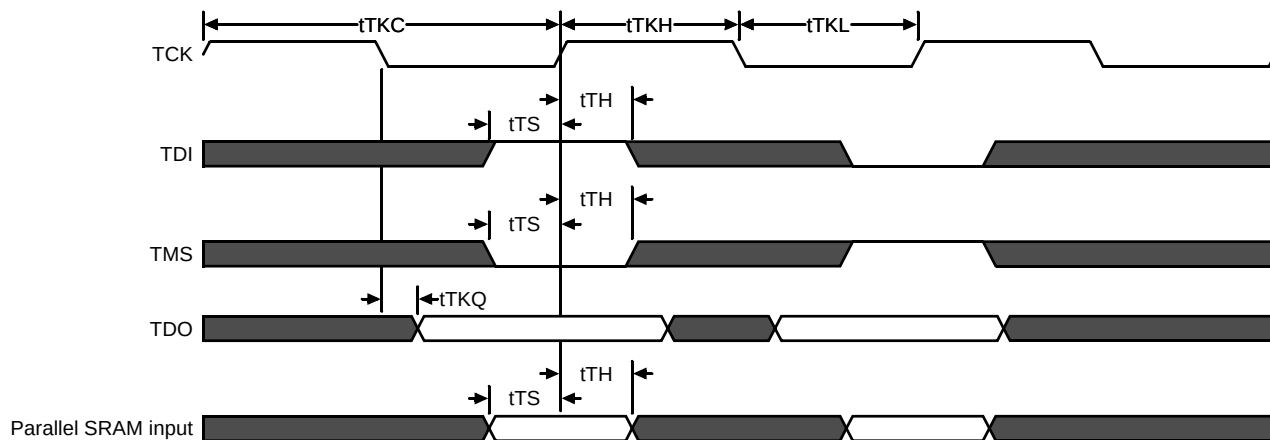
| Parameter              | Conditions               |
|------------------------|--------------------------|
| Input high level       | $V_{DD} - 0.2 \text{ V}$ |
| Input low level        | 0.2 V                    |
| Input slew rate        | 1 V/ns                   |
| Input reference level  | $V_{DDQ}/2$              |
| Output reference level | $V_{DDQ}/2$              |

### Notes:

- Include scope and jig capacitance.
- Test conditions as shown unless otherwise noted.



### JTAG Port Timing Diagram



### JTAG Port AC Electrical Characteristics

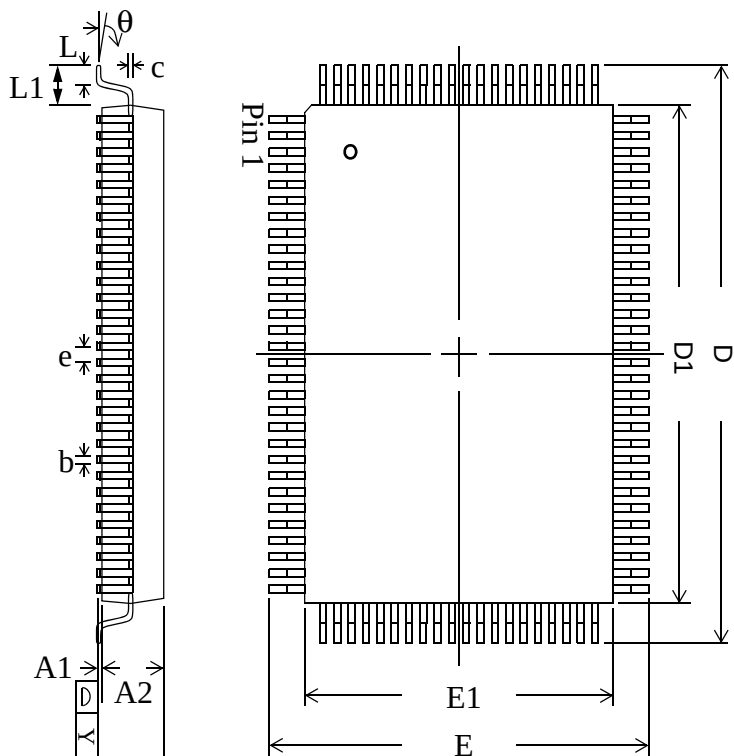
| Parameter             | Symbol    | Min | Max | Unit |
|-----------------------|-----------|-----|-----|------|
| TCK Cycle Time        | $t_{TKC}$ | 50  | —   | ns   |
| TCK Low to TDO Valid  | $t_{TKQ}$ | —   | 20  | ns   |
| TCK High Pulse Width  | $t_{TKH}$ | 20  | —   | ns   |
| TCK Low Pulse Width   | $t_{TKL}$ | 20  | —   | ns   |
| TDI & TMS Set Up Time | $t_{TS}$  | 10  | —   | ns   |
| TDI & TMS Hold Time   | $t_{TH}$  | 10  | —   | ns   |

### Boundary Scan (BSDL Files)

For information regarding the Boundary Scan Chain, or to obtain BSDL files for this part, please contact our Applications Engineering Department at: [apps@gsitechnology.com](mailto:apps@gsitechnology.com).

## TQFP Package Drawing (Package T)

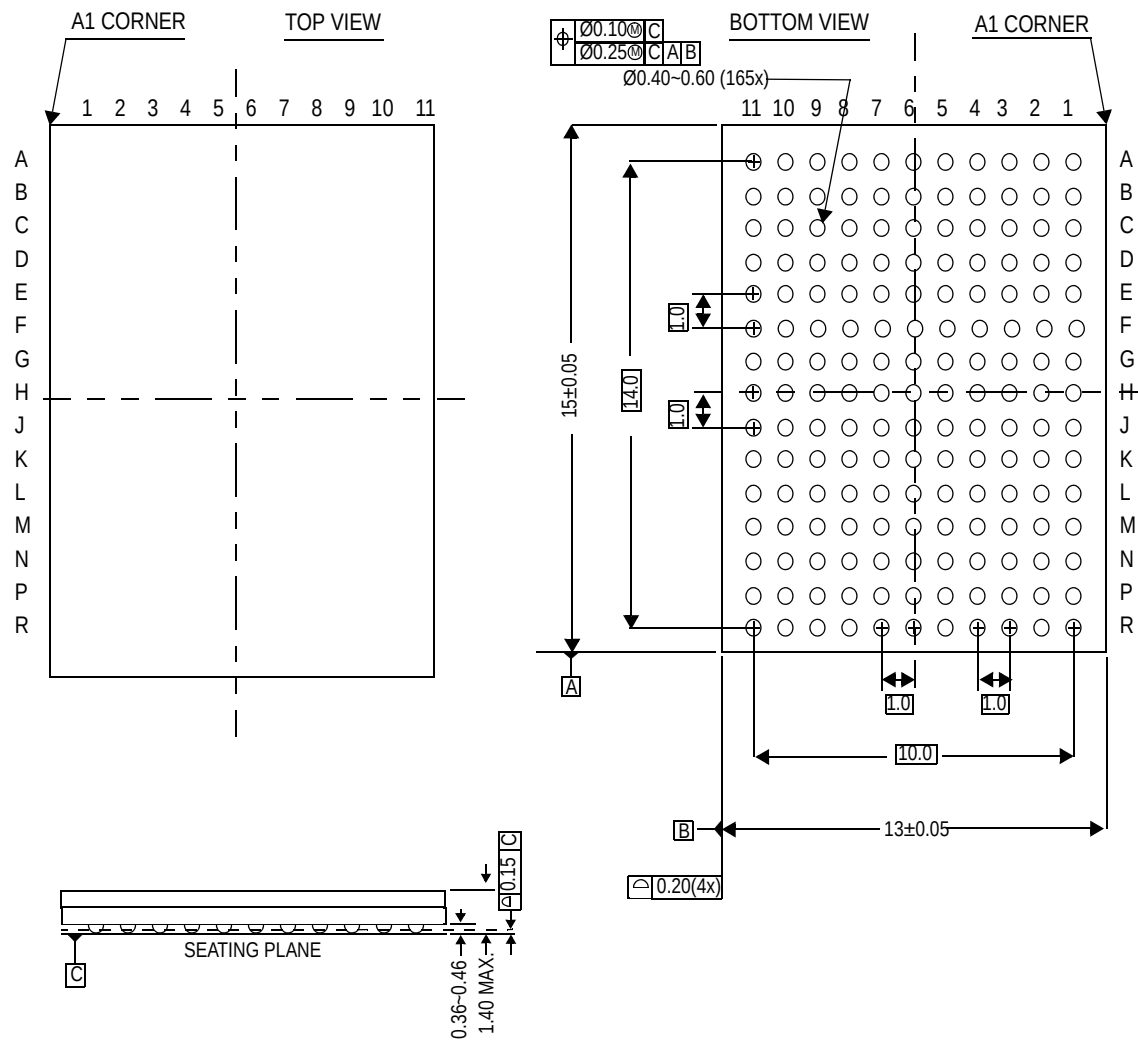
| Symbol   | Description        | Min. | Nom. | Max  |
|----------|--------------------|------|------|------|
| A1       | Standoff           | 0.05 | 0.10 | 0.15 |
| A2       | Body Thickness     | 1.35 | 1.40 | 1.45 |
| b        | Lead Width         | 0.20 | 0.30 | 0.40 |
| c        | Lead Thickness     | 0.09 | —    | 0.20 |
| D        | Terminal Dimension | 21.9 | 22.0 | 22.1 |
| D1       | Package Body       | 19.9 | 20.0 | 20.1 |
| E        | Terminal Dimension | 15.9 | 16.0 | 16.1 |
| E1       | Package Body       | 13.9 | 14.0 | 14.1 |
| e        | Lead Pitch         | —    | 0.65 | —    |
| L        | Foot Length        | 0.45 | 0.60 | 0.75 |
| L1       | Lead Length        | —    | 1.00 | —    |
| Y        | Coplanarity        |      |      | 0.10 |
| $\theta$ | Lead Angle         | 0°   | —    | 7°   |



## Notes:

1. All dimensions are in millimeters (mm).
2. Package width and length do not include mold protrusion.

### Package Dimensions—165-Bump FPBGA (Package D)



## Ordering Information for GSI Synchronous Burst RAMs

| Org       | Part Number <sup>1</sup> | Type              | Voltage Option | Package                | Speed <sup>2</sup><br>(MHz/ns) | T <sub>A</sub> <sup>3</sup> |
|-----------|--------------------------|-------------------|----------------|------------------------|--------------------------------|-----------------------------|
| 512K x 18 | GS88118CT-250IV          | Synchronous Burst | 1.8 V or 2.5 V | TQFP                   | 250/5.5                        | I                           |
| 512K x 18 | GS88118CT-200IV          | Synchronous Burst | 1.8 V or 2.5 V | TQFP                   | 200/6.5                        | I                           |
| 512K x 18 | GS88118CT-150IV          | Synchronous Burst | 1.8 V or 2.5 V | TQFP                   | 150/7.5                        | I                           |
| 256K x 32 | GS88136CT-250IV          | Synchronous Burst | 1.8 V or 2.5 V | TQFP                   | 250/5.5                        | I                           |
| 256K x 32 | GS88132CT-200IV          | Synchronous Burst | 1.8 V or 2.5 V | TQFP                   | 200/6.5                        | I                           |
| 256K x 32 | GS88132CT-150IV          | Synchronous Burst | 1.8 V or 2.5 V | TQFP                   | 150/7.5                        | I                           |
| 256K x 36 | GS88136CT-250IV          | Synchronous Burst | 1.8 V or 2.5 V | TQFP                   | 250/5.5                        | I                           |
| 256K x 36 | GS88136CT-200IV          | Synchronous Burst | 1.8 V or 2.5 V | TQFP                   | 200/6.5                        | I                           |
| 256K x 36 | GS88136CT-150IV          | Synchronous Burst | 1.8 V or 2.5 V | TQFP                   | 150/7.5                        | I                           |
| 512K x 18 | GS88118CGT-250IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant TQFP    | 250/5.5                        | I                           |
| 512K x 18 | GS88118CGT-200IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant TQFP    | 200/6.5                        | I                           |
| 512K x 18 | GS88118CGT-150IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant TQFP    | 150/7.5                        | I                           |
| 256K x 32 | GS88136CGT-250IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant TQFP    | 250/5.5                        | I                           |
| 256K x 32 | GS88132CGT-200IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant TQFP    | 200/6.5                        | I                           |
| 256K x 32 | GS88132CGT-150IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant TQFP    | 150/7.5                        | I                           |
| 256K x 36 | GS88136CGT-250IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant TQFP    | 250/5.5                        | I                           |
| 256K x 36 | GS88136CGT-200IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant TQFP    | 200/6.5                        | I                           |
| 256K x 36 | GS88136CGT-150IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant TQFP    | 150/7.5                        | I                           |
| 512K x 18 | GS88118CD-250IV          | Synchronous Burst | 1.8 V or 2.5 V | 165 BGA                | 250/5.5                        | I                           |
| 512K x 18 | GS88118CD-200IV          | Synchronous Burst | 1.8 V or 2.5 V | 165 BGA                | 200/6.5                        | I                           |
| 512K x 18 | GS88118CD-150IV          | Synchronous Burst | 1.8 V or 2.5 V | 165 BGA                | 150/7.5                        | I                           |
| 256K x 32 | GS88132CD-250IV          | Synchronous Burst | 1.8 V or 2.5 V | 165 BGA                | 250/5.5                        | I                           |
| 256K x 32 | GS88132CD-200IV          | Synchronous Burst | 1.8 V or 2.5 V | 165 BGA                | 200/6.5                        | I                           |
| 256K x 32 | GS88132CD-150IV          | Synchronous Burst | 1.8 V or 2.5 V | 165 BGA                | 150/7.5                        | I                           |
| 256K x 36 | GS88136CD-250IV          | Synchronous Burst | 1.8 V or 2.5 V | 165 BGA                | 250/5.5                        | I                           |
| 256K x 36 | GS88136CD-200IV          | Synchronous Burst | 1.8 V or 2.5 V | 165 BGA                | 200/6.5                        | I                           |
| 256K x 36 | GS88136CD-150IV          | Synchronous Burst | 1.8 V or 2.5 V | 165 BGA                | 150/7.5                        | I                           |
| 512K x 18 | GS88118CGD-250IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant 165 BGA | 250/5.5                        | I                           |
| 512K x 18 | GS88118CGD-200IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant 165 BGA | 200/6.5                        | I                           |

### Notes:

- Customers requiring delivery in Tape and Reel should add the character "T" to the end of the part number. Example: GS88118CT-150IVT.
- The speed column indicates the cycle frequency (MHz) of the device in Pipeline mode and the latency (ns) in Flow Through mode. Each device is Pipeline/Flow Through mode-selectable by the user.
- T<sub>A</sub> = I = Industrial Temperature Range.
- GSI offers other versions this type of device in many different configurations and with a variety of different features, only some of which are covered in this data sheet. See the GSI Technology web site ([www.gsistechnology.com](http://www.gsistechnology.com)) for a complete listing of current offerings.

# Ordering Information for GSI Synchronous Burst RAMs (Continued)

| Org       | Part Number <sup>1</sup> | Type              | Voltage Option | Package                | Speed <sup>2</sup><br>(MHz/ns) | T <sub>A</sub> <sup>3</sup> |
|-----------|--------------------------|-------------------|----------------|------------------------|--------------------------------|-----------------------------|
| 512K x 18 | GS88118CGD-150IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant 165 BGA | 150/7.5                        | I                           |
| 256K x 32 | GS88132CGD-250IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant 165 BGA | 250/5.5                        | I                           |
| 256K x 32 | GS88132CGD-200IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant 165 BGA | 200/6.5                        | I                           |
| 256K x 32 | GS88136CGD-150IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant 165 BGA | 150/7.5                        | I                           |
| 256K x 36 | GS88136CGD-250IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant 165 BGA | 250/5.5                        | I                           |
| 256K x 36 | GS88136CGD-200IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant 165 BGA | 200/6.5                        | I                           |
| 256K x 36 | GS88136CGD-150IV         | Synchronous Burst | 1.8 V or 2.5 V | RoHS-compliant 165 BGA | 150/7.5                        | I                           |

## Notes:

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- The speed column indicates the cycle frequency (MHz) of the device in Pipeline mode and the latency (ns) in Flow Through mode. Each device is Pipeline/Flow Through mode-selectable by the user.
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## 9Mb Sync SRAM Datasheet Revision History

| File Name          | Types of Changes<br>Format or Content | Revision                                                                                            |
|--------------------|---------------------------------------|-----------------------------------------------------------------------------------------------------|
| 881xxC_V_r1        |                                       | • Creation of new datasheet                                                                         |
| 881xxC_V_r1_01     | Content                               | • Update to MP datasheet                                                                            |
| 881xxC_V_r1_02     | Content                               | • Updated Absolute Maximum Ratings<br>• Deleted conditional text                                    |
| 881xxC_V_r1_03     | Content                               | • Updated Absolute Maximum Ratings<br>• Added thermal information<br>• Updated Ordering Information |
| 881xxC_V_r1_04_Ind | Content                               | • Updated Absolute Maximum Ratings<br>• Removed all Comm Temp references                            |

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105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

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